



16-BIT, 600-kHz, PSEUDO-DIFFERENTIAL INPUT, MICROPOWER SAMPLING ANALOG-TO-DIGITAL CONVERTER WITH SERIAL INTERFACE AND REFERENCE

FEATURES

- 600-kHz Sample Rate
- ± 0.5 LSB Typ, ± 1.25 LSB Max INL
- ± 0.4 LSB Typ, ± 0.75 LSB Max DNL
- 16-Bit NMC
- SINAD 89.5 dB, SFDR 119 dB at $f_i = 1$ kHz
- High-Speed Serial Interface up to 40 MHz
- Onboard Reference Buffer
- Onboard 4.096-V Reference
- Pseudo-Differential Input, 0 V to 4.2 V
- Onboard Conversion Clock
- Selectable Output Format, 2's Complement or Straight Binary
- Zero Latency
- Wide Digital Supply
- Low Power:
 - 110 mW at 600 kHz
 - 15 mW During Nap Mode
 - 10 μ W During Power Down
- 28-Pin 6 x 6 QFN Package

- Pin compatible With 18-Bit ADS8380

APPLICATIONS

- Medical Instruments
- Optical Networking
- Transducer Interface
- High Accuracy Data Acquisition Systems
- Magnetometers

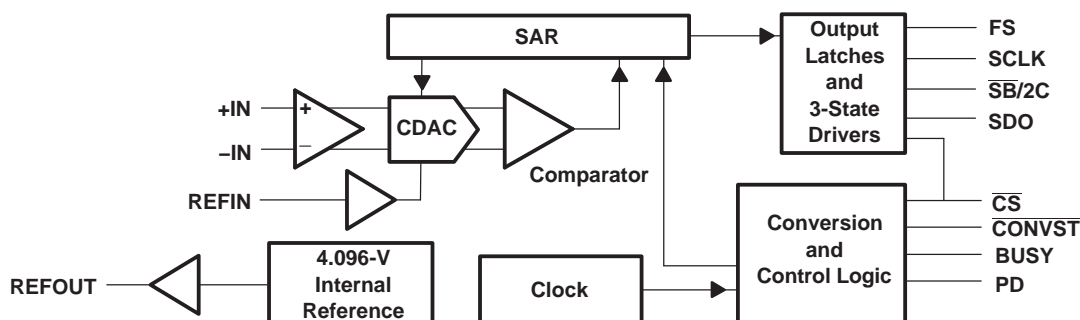
DESCRIPTION

The ADS8370 is a high performance 16-bit, 600-kHz A/D converter with single-ended (pseudo-differential) input. The device includes an 16-bit capacitor-based SAR A/D converter with inherent sample and hold. The ADS8370 offers a high-speed CMOS serial interface with clock speeds up to 40 MHz.

The ADS8370 is available in a 28 lead 6 x 6 QFN package and is characterized over the industrial -40°C to 85°C temperature range.

High Speed SAR Converter Family

Type/Speed	500 kHz	~ 600 kHz	750 kHz	1 MHz	1.25 MHz	2 MHz	3 MHz	4 MHz
18-Bit Pseudo-Diff	ADS8383	ADS8381						
		ADS8380 (S)						
18-Bit Pseudo-Bipolar, Fully Diff		ADS8382 (S)						
16-Bit Pseudo-Diff		ADS8370 (S)	ADS8371		ADS8401/05	ADS8411		
16-Bit Pseudo-Bipolar, Fully Diff		ADS8372 (S)			ADS8402/06	ADS8412		
14-Bit Pseudo-Diff					ADS7890 (S)		ADS7891	
12-Bit Pseudo-Diff				ADS7886				ADS7881



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ORDERING INFORMATION⁽¹⁾

MODEL	MAXIMUM INTEGRAL LINEARITY (LSB)	MAXIMUM DIFFERENTIAL LINEARITY (LSB)	NO MISSING CODES RESOLUTION (BIT)	PACKAGE TYPE	PACKAGE DESIGNATOR	TEMPERATURE RANGE	ORDERING INFORMATION	TRANSPORT MEDIA QUANTITY
ADS8370I	±2	–1/1.5	16	28 Pin 6x6 QFN	RHP	–40°C to 85°C	ADS8370IRHPT	Small Tape and reel 250
							ADS8370IRHPR	Tape and reel 2500
ADS8370IB	±1.25	±0.75	16	28 Pin 6x6 QFN	RHP	–40°C to 85°C	ADS8370IBRHPT	Small Tape and reel 250
							ADS8370IBRHPR	Tape and reel 2500

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range unless otherwise noted⁽¹⁾

		UNIT
Voltage	+IN to AGND	–0.3 V to +VA + 0.3 V
	–IN to AGND	–0.3 V to +VA + 0.3 V
	+VA to AGND	–0.3 V to 6 V
	+VBD to BDGND	–0.3 V to 6 V
Digital input voltage to BDGND		–0.3 V to +VBD + 0.3 V
Digital input voltage to +VA		+0.3 V
Operating free-air temperature range, T _A		–40°C to 85°C
Storage temperature range, T _{stg}		–65°C to 150°C
Junction temperature (T _J max)		150°C
QFN package	Power dissipation	(T _J max – T _A)/θ _{JA}
	θ _{JA} thermal impedance	86°C/W
Lead temperature, soldering	Vapor phase (60 sec)	215°C
	Infrared (15 sec)	220°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

SPECIFICATIONS

At -40°C to 85°C , $+V_A = +5\text{ V}$, $+V_{BD} = +5\text{ V}$ or $+V_{BD} = +2.7\text{ V}$, using internal or external reference, $f_{\text{SAMPLE}} = 600\text{ kHz}$, unless otherwise noted. (All performance parameters are valid only after device has properly resumed from power down, see [Table 2](#).)

PARAMETER		TEST CONDITIONS	ADS8370IB			ADS8370I			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
ANALOG INPUT										
Full-scale input voltage ⁽¹⁾		+IN – (–IN)	0		V _{ref}		0		V _{ref}	V
Absolute input voltage		+IN	–0.2		V _{ref} + 0.2		–0.2		V _{ref} + 0.2	V
		–IN	–0.2		0.2		–0.2		0.2	
Sampling capacitance (measured from ±IN to AGND)			40			40			pF	
Input leakage current			1			1			nA	
SYSTEM PERFORMANCE										
Resolution			16			16			Bits	
No missing codes			16			16			Bits	
INL	Integral linearity ⁽²⁾⁽³⁾⁽⁴⁾	Quiet zones observed	–1.25	±0.5	1.25	–2		2	LSB (16 bit)	
		Quiet zones not observed	±0.8							
DNL	Differential linearity ⁽³⁾	Quiet zones observed	–0.75	±0.4	0.75	–1		1.5	LSB (16 bit)	
		Quiet zones not observed	±0.75							
E _O	Offset error ⁽³⁾		–0.75	±0.4	0.75	–1.5		1.5	mV	
Offset temperature drift ⁽³⁾			±0.4			±0.4			ppm/°C	
E _G	Gain error ⁽³⁾⁽⁵⁾		–0.075		0.075	–0.15		0.15	%FS	
Gain temperature drift ⁽³⁾⁽⁵⁾			±1.25			±1.25			ppm/°C	
CMRR	Common-mode rejection ratio	At DC	80			80			dB	
		[+IN – (–IN)] = V _{ref} /2 with 50 mV _{p-p} common mode signal at 1 MHz	55			55				
Noise		At 0 V analog input	40			40			μV RMS	
PSRR	DC Power supply rejection ratio	At full scale analog input	55			55			dB	
SAMPLING DYNAMICS										
Conversion time			1.0		1.16	1.0		1.16	μs	
Acquisition time			0.50			0.50			μs	
Throughput rate			600			600			kHz	
Aperture delay			10			10			ns	
Aperture jitter			12			12			ps RMS	
Step response		⁽⁶⁾	400			400			ns	
Overvoltage recovery			400			400			ns	

(1) Ideal input span; does not include gain or offset error.

(2) LSB means least significant bit.

(3) Measured using analog input circuit in [Figure 51](#) and digital stimulus in [Figure 56](#) and [Figure 57](#) and reference voltage of 4.096 V.

(4) This is endpoint INL, not best fit.

(5) Measured using external reference source so does not include internal reference voltage error or drift.

(6) Defined as sampling time necessary to settle an initial error of V_{ref} on the sampling capacitor to a final error of 1 LSB at 16-bit level. Measured using the input circuit in [Figure 51](#).

SPECIFICATIONS (continued)

At -40°C to 85°C , $+V_A = +5\text{ V}$, $+V_{BD} = +5\text{ V}$ or $+V_{BD} = +2.7\text{ V}$, using internal or external reference, $f_{\text{SAMPLE}} = 600\text{ kHz}$, unless otherwise noted. (All performance parameters are valid only after device has properly resumed from power down, see Table 2.)

PARAMETER		TEST CONDITIONS	ADS8370IB			ADS8370I			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
DYNAMIC CHARACTERISTICS									
THD	Total harmonic distortion ⁽⁷⁾⁽⁸⁾	VIN = 4 V _{p-p} at 1 kHz	–112			–111			dB
		VIN = 4 V _{p-p} at 10 kHz	–111			–111			
		VIN = 4 V _{p-p} at 100 kHz	–92			–92			
SNR	Signal-to-noise ratio ⁽⁷⁾	VIN = 4 V _{p-p} at 1 kHz	89.5			89.5			dB
		VIN = 4 V _{p-p} at 10 kHz	89.5			89			
		VIN = 4 V _{p-p} at 100 kHz	89.5			88.5			
SINAD	Signal-to-noise + distortion ⁽⁷⁾⁽⁸⁾	VIN = 4 V _{p-p} at 1 kHz	89.5			89.5			dB
		VIN = 4 V _{p-p} at 10 kHz	89.5			89			
		VIN = 4 V _{p-p} at 100 kHz	87.5			87			
SFDR	Spurious free dynamic range ⁽⁷⁾	VIN = 4 V _{p-p} at 1 kHz	119			119			dB
		VIN = 4 V _{p-p} at 10 kHz	117			117			
		VIN = 4 V _{p-p} at 100 kHz	92			92			
–3dB Small signal bandwidth			75			75			MHz
REFERENCE INPUT									
V _{ref}	Reference voltage input range		2.5	4.096	4.2	2.5	4.096	4.2	V
	Resistance ⁽⁹⁾		10			10			MΩ
INTERNAL REFERENCE OUTPUT									
V _{ref}	Reference voltage range	IOUT = 0 A, T _A = 30°C	4.088	4.096	4.104	4.088	4.096	4.104	V
	Source current	Static load	10			10			μA
	Line regulation	+VA = 4.75 V to 5.25 V	2.5			2.5			mV
	Drift	IOUT = 0 A	25			25			ppm/°C
DIGITAL INPUT/OUTPUT									
Logic family CMOS									
V _{IH}	High level input voltage		+VBD – 1	+VBD + 0.3		+VBD – 1	+VBD + 0.3		V
V _{IL}	Low level input voltage		–0.3	0.8		–0.3	0.8		V
V _{OH}	High level output voltage	I _{OH} = 2 TTL loads	+VBD –0.6			+VBD –0.6			V
V _{OL}	Low level output voltage	I _{OL} = 2 TTL loads	0.4			0.4			V
Data format: MSB first, 2's complement or straight binary (selectable via the SB/2C pin)									
POWER SUPPLY REQUIREMENTS									
	Power supply voltage	+VA	4.75	5	5.25	4.75	5	5.25	V
		+VBD	2.7	3.3	5.25	2.7	3.3	5.25	V
I _{CC}	Supply current, 600-kHz sample rate ⁽¹⁰⁾	+VA = 5 V		22	25		22	25	mA
POWER DOWN									
I _{CC(PD)}	Supply current, power down		2			2			μA
NAP MODE									
I _{CC(NAP)}	Supply current, nap mode		3			3			mA
Power-up time from nap			300			300			ns
TEMPERATURE RANGE									
Specified performance			–40		85	–40		85	°C

(7) Measured using analog input circuit in Figure 51 and digital stimulus in Figure 56 and Figure 57 and reference voltage of 4.096 V.

(8) Calculated on the first nine harmonics of the input frequency.

(9) Can vary +/-30%.

(10) This includes only +V_A current. With +V_{BD} = 5 V, +V_{BD} current is typically 1 mA with a 10-pF load capacitance on the digital output pins.

TIMING REQUIREMENTS⁽¹⁾⁽²⁾⁽³⁾⁽⁴⁾⁽⁵⁾⁽⁶⁾

PARAMETER		ADS8370I/ADS8370IB			UNIT	REF FIGURE
		MIN	TYP	MAX		
t _{conv}	Conversion time	1000		1160	ns	41 – 44
t _{acq1}	Acquisition time in normal mode	0.5			μs	41,42,44
t _{acq2}	Acquisition time in nap mode (t _{acq2} = t _{acq1} + t _{d18})	0.8			μs	43
CONVERSION AND SAMPLING						
t _{quiet1}	Quiet sampling time (last toggle of interface signals to convert start command) ⁽⁶⁾	30			ns	40 – 43, 45 – 47
t _{quiet2}	Quiet sampling time (convert start command to first toggle of interface signals) ⁽⁶⁾	10			ns	40 – 43, 45 – 47
t _{quiet3}	Quiet conversion time (last toggle of interface signals to fall of BUSY) ⁽⁶⁾	600			ns	40 – 43, 45,47
t _{su1}	Setup time, $\overline{\text{CONVST}}$ before BUSY fall	15			ns	41
t _{su2}	Setup time, $\overline{\text{CS}}$ before BUSY fall (only for conversion/sampling control)	20			ns	40,41
t _{su4}	Setup time, $\overline{\text{CONVST}}$ before $\overline{\text{CS}}$ rise (so $\overline{\text{CONVST}}$ can be recognized)	5			ns	41,43,44
t _{h1}	Hold time, $\overline{\text{CS}}$ after BUSY fall (only for conversion/sampling control)	0			ns	41
t _{h3}	Hold time, $\overline{\text{CONVST}}$ after $\overline{\text{CS}}$ rise	7			ns	43
t _{h4}	Hold time, $\overline{\text{CONVST}}$ after $\overline{\text{CS}}$ fall (to ensure width of $\overline{\text{CONVST_QUAL}}$) ⁽⁴⁾	20			ns	42
t _{w1}	$\overline{\text{CONVST}}$ pulse duration	20			ns	43
t _{w2}	$\overline{\text{CS}}$ pulse duration	10			ns	41,42
t _{w5}	Pulse duration, time between conversion start command and conversion abort command to successfully abort the ongoing conversion			1000	ns	44
DATA READ OPERATION						
t _{cyc}	SCLK period	25			ns	45 – 47
	SCLK duty cycle	40%		60%		
t _{su5}	Setup time, $\overline{\text{CS}}$ fall before first SCLK fall	10			ns	45
t _{su6}	Setup time, $\overline{\text{CS}}$ fall before FS rise	7			ns	46,47
t _{su7}	Setup time, FS fall before first SCLK fall	7			ns	46,47
t _{h5}	Hold time, $\overline{\text{CS}}$ fall after SCLK fall	3			ns	45
t _{h6}	Hold time, FS fall after SCLK fall	7			ns	46,47
t _{su2}	Setup time, $\overline{\text{CS}}$ fall before BUSY fall (only for read control)	20			ns	40,45
t _{su3}	Setup time, FS fall before BUSY fall (only for read control)	20			ns	40,47
t _{h2}	Hold time, $\overline{\text{CS}}$ fall after BUSY fall (only for read control)	15			ns	40,45
t _{h8}	Hold time, FS fall after BUSY fall (only for read control)	15			ns	40,47
t _{w2}	$\overline{\text{CS}}$ pulse duration	10			ns	45
t _{w3}	FS pulse duration	10			ns	46,47
MISCELLANEOUS						
t _{w4}	PD pulse duration for reset and power down	60			ns	53,54
	All unspecified pulse durations	10			ns	

(1) All input signals are specified with t_r = t_f = 5 ns (10% to 90% of V_{DD}) and timed from a voltage level of (V_{IL} + V_{IH})/2.

(2) All specifications typical at –40°C to 85°C, +VA = +4.75 V to +5.25 V, +VBD = +2.7 V to +5.25 V.

(3) All digital output signals loaded with 10-pF capacitors.

(4) $\overline{\text{CONVST_QUAL}}$ is $\overline{\text{CONVST}}$ latched by a low value on $\overline{\text{CS}}$ (see Figure 39).

(5) Reference figure indicated is only a representative of where the timing is applicable and is not exhaustive.

(6) Quiet time zones are for meeting performance and not functionality.

TIMING CHARACTERISTICS⁽¹⁾⁽²⁾⁽³⁾⁽⁴⁾

PARAMETER		ADS8370I/ADS8370IB			UNIT	REF FIGURE
		MIN	TYP	MAX		
CONVERSION AND SAMPLING						
t _{d1}	Delay time, conversion start command to conversion start (aperture delay)			10	ns	41,43
t _{d2}	Delay time, conversion end to BUSY fall			5	ns	41 – 43
t _{d4}	Delay time, conversion start command to BUSY rise			20	ns	41
t _{d3}	Delay time, $\overline{\text{CONVST}}$ rise to sample start			5	ns	43
t _{d5}	Delay time, $\overline{\text{CS}}$ fall to sample start			10	ns	43
t _{d6}	Delay time, conversion abort command to BUSY fall			10	ns	44
DATA READ OPERATION						
t _{d12}	Delay time, $\overline{\text{CS}}$ fall to MSB valid			3	15	ns 45
t _{d15}	Delay time, FS rise to MSB valid			6	18	ns 46,47
t _{d7}	Delay time, BUSY fall to MSB valid (if FS is high when BUSY falls)				18	ns 47
t _{d13}	Delay time, SCLK rise to bit valid			2	10	ns 45– 47
t _{d14}	Delay time, $\overline{\text{CS}}$ rise to SDO 3-state				6	ns 45
MISCELLANEOUS						
t _{d10}	Delay time, PD rise to SDO 3-state				55	ns 53,54
t _{d18}	Delay time, total device resume time	Nap mode			300	ns 55
		Full power down (external reference used with or without 1-μF 0.1-μF capacitor on REFOUT)			t _{d11} + 2x conversions	54
		Full power down (internal reference used with or without 1-μF 0.1-μF capacitor on REFOUT)			25 ⁽⁴⁾	ms 53
t _{d11}	Delay time, untrimmed circuit full power-down resume time				1	ms 53,54
t _{d16}	Delay time, device power-down time	Nap			200	ns 55
		Full power down (internal/external reference used)			10	μs 53,54
t _{d17}	Delay time, trimmed internal reference settling (either by turning on supply or resuming from full power-down mode), with 1-μF 0.1-μF capacitor on REFOUT				4	ms 53

(1) All input signals are specified with $t_r = t_f = 5$ ns (10% to 90% of V_{DD}) and timed from a voltage level of $(V_{IL} + V_{IH})/2$.

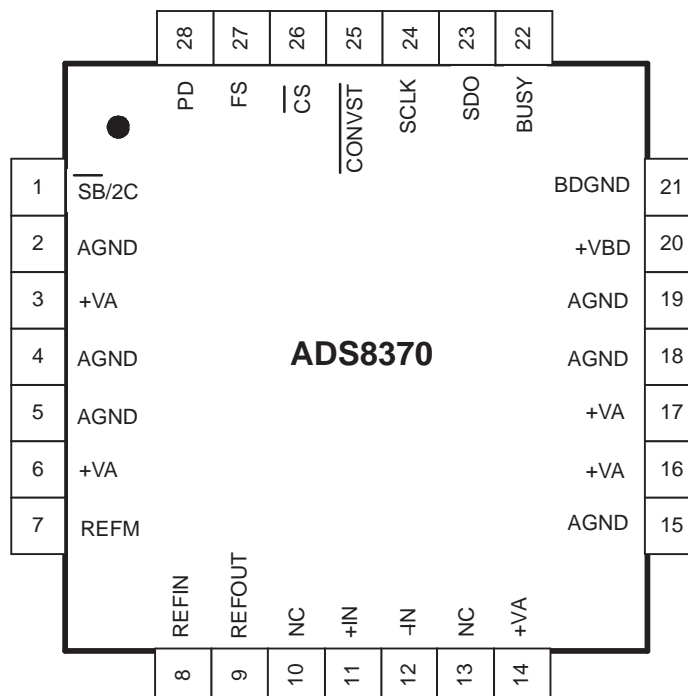
(2) All specifications typical at -40°C to 85°C , $+V_A = +4.75$ V to $+5.25$ V, $+V_{BD} = +2.7$ V to $+5.25$ V.

(3) All digital output signals loaded with 10-pF capacitors.

(4) Including t_{d11} , two conversions (time to cycle $\overline{\text{CONVST}}$ twice), and t_{d17} .

PIN ASSIGNMENTS

TOP VIEW



Note: The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

TERMINAL FUNCTIONS

PIN		I/O	DESCRIPTION
NAME	NO.		
AGND	2, 4, 5, 15, 18, 19	–	Analog ground pins. AGND must be shorted to analog ground plane below the device.
BDGND	21	–	Digital ground for all digital inputs and outputs. BDGND must be shorted to the analog ground plane below the device.
BUSY	22	O	Status output. This pin is high when conversion is in progress.
CONVST	25	I	Convert start. This signal is qualified with \overline{CS} internally.
CS	26	I	Chip select
FS	27	I	Frame sync. This signal is qualified with \overline{CS} internally.
+IN	11	I	Noninverting analog input channel
–IN	12	I	Inverting analog input channel
NC	10, 13	–	No connection
PD	28	I	Power down. Device resets and powers down when this signal is high.
REFIN	8	I	Reference (positive) input. REFIN must be decoupled with REFM pin using 0.1-μF bypass capacitor and 1-μF storage capacitor.
REFM	7	I	Reference ground. To be connected to analog ground plane.
REFOUT	9	O	Internal reference output. Shorted to REFIN pin only when internal reference is used.
SB/2C	1	I	Straight binary or 2's complement output data format. When low the device output is straight binary format; when high the device output is 2's complement format. See Table 1 .
SCLK	24	I	Serial clock. Data is shifted onto SDO with the rising edge of this clock. This signal is qualified with \overline{CS} internally.
SDO	23	O	Serial data out. All bits except MSB are shifted out at the rising edge of SCLK.
+VA	3, 6, 14, 16, 17	–	Analog power supplies
+VBD	20	–	Digital power supply for all digital inputs and outputs.

TYPICAL CHARACTERISTICS

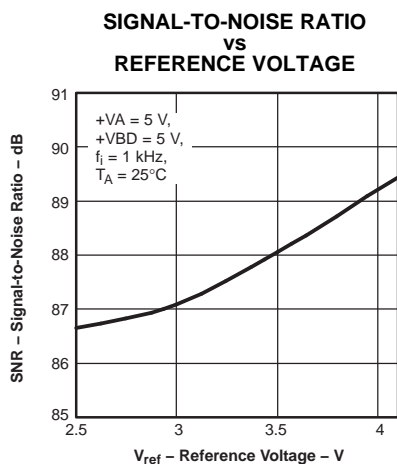


Figure 1.

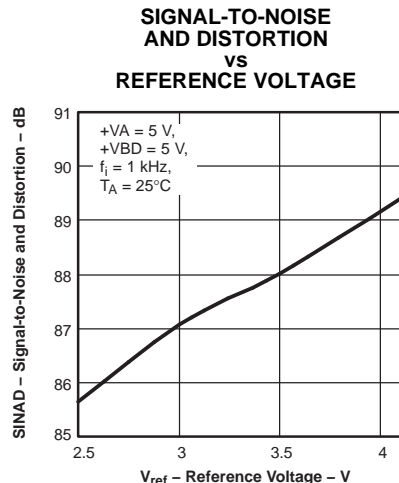


Figure 2.

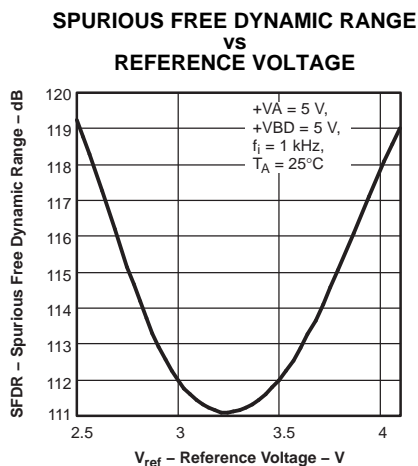


Figure 3.

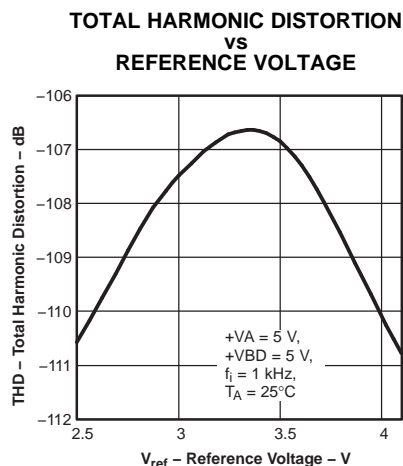


Figure 4.

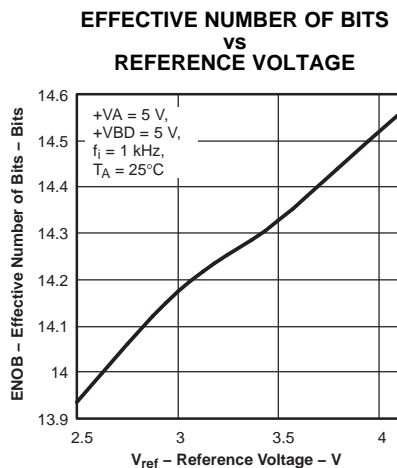


Figure 5.

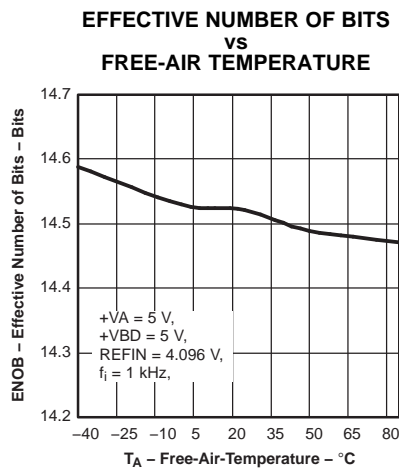


Figure 6.

TYPICAL CHARACTERISTICS (continued)

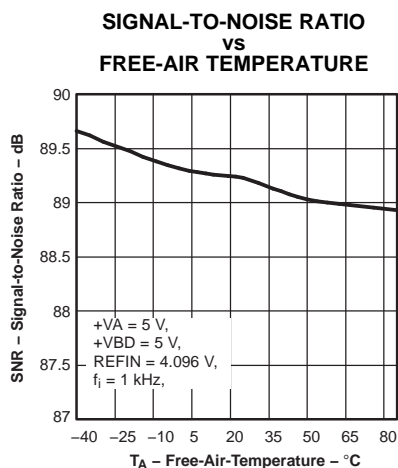


Figure 7.

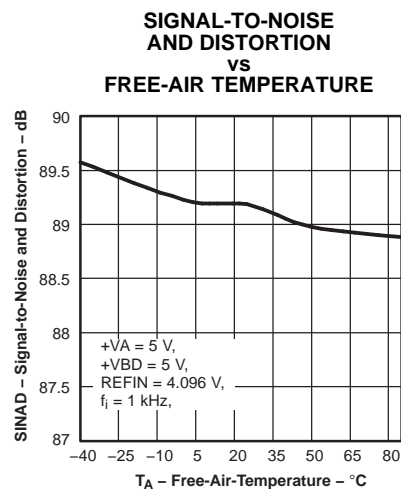


Figure 8.

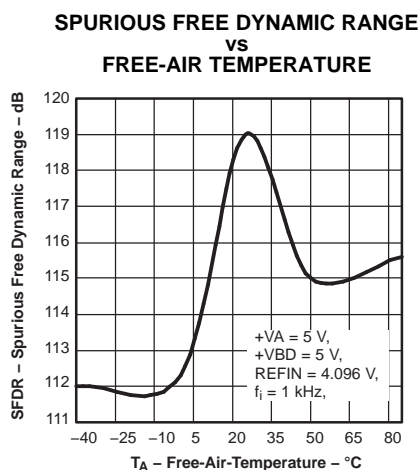


Figure 9.

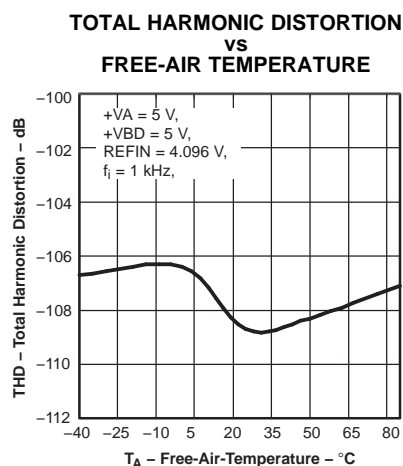


Figure 10.

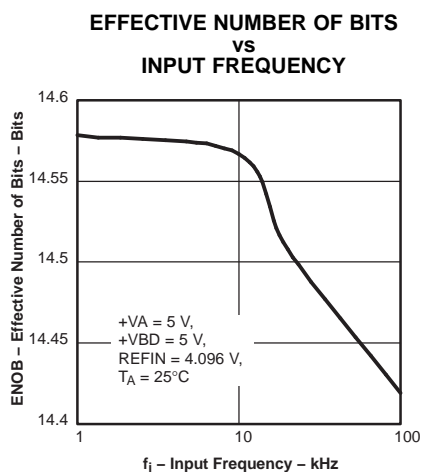


Figure 11.

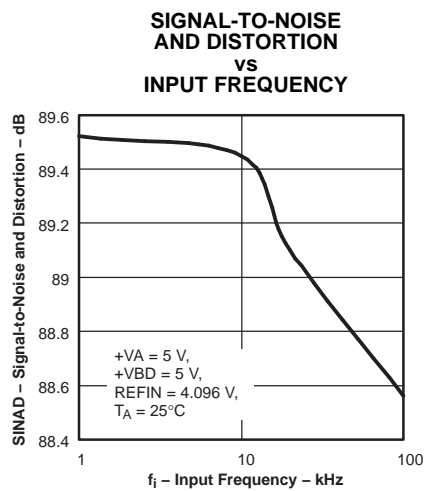


Figure 12.

TYPICAL CHARACTERISTICS (continued)

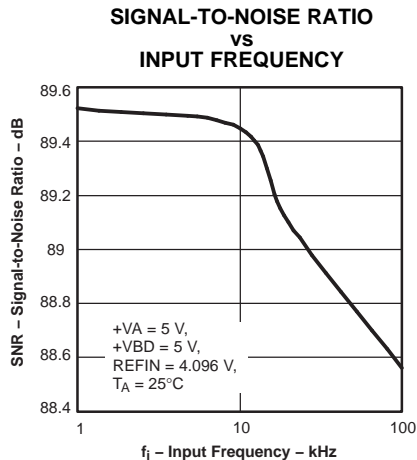


Figure 13.

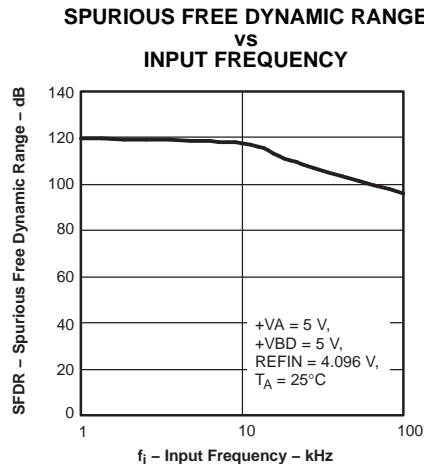


Figure 14.

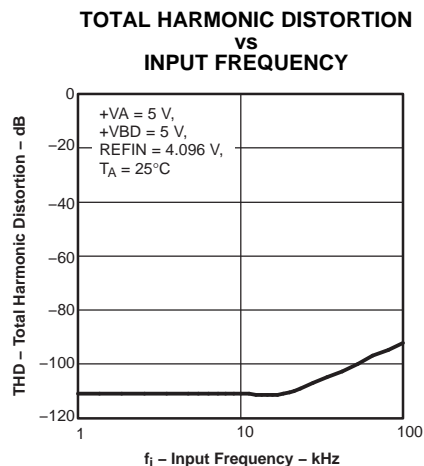


Figure 15.

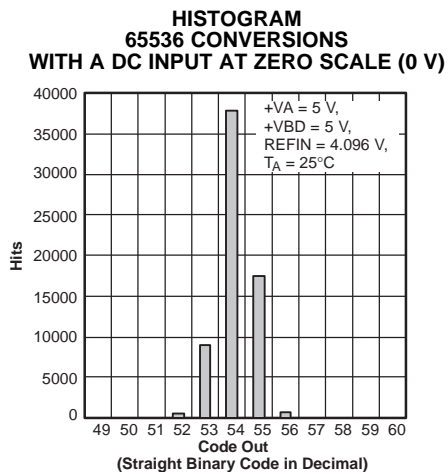


Figure 16.

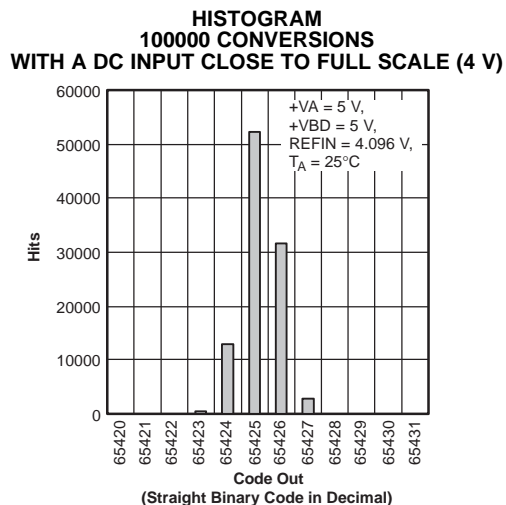


Figure 17.

TYPICAL CHARACTERISTICS (continued)

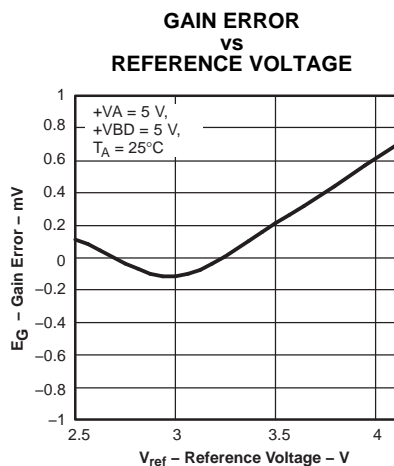


Figure 18.

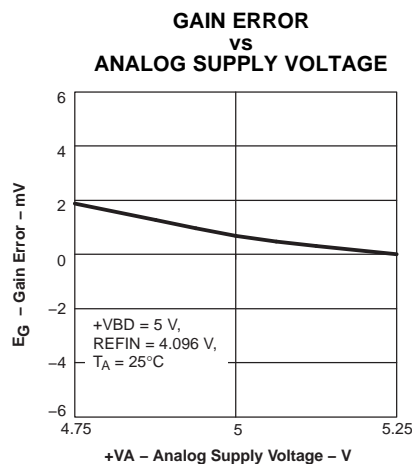


Figure 19.

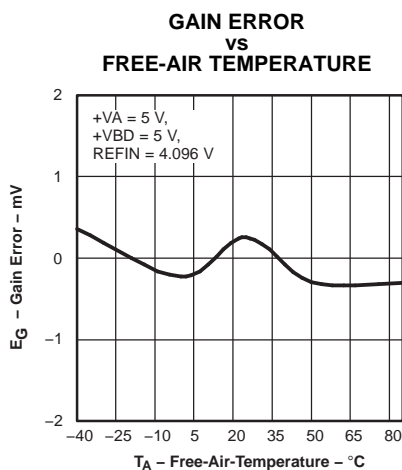


Figure 20.

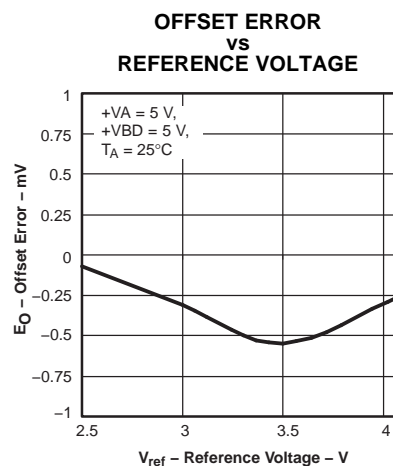


Figure 21.

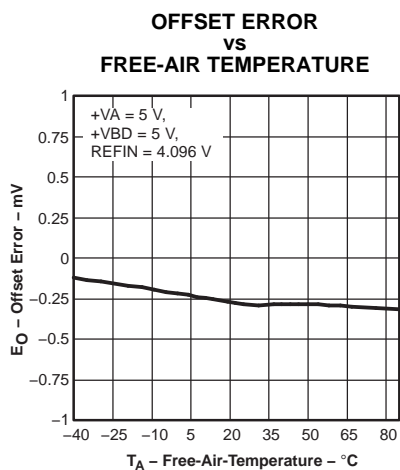


Figure 22.

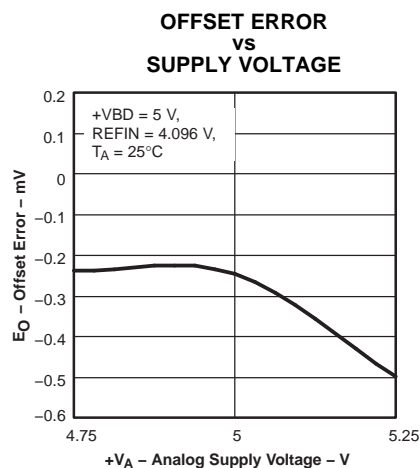


Figure 23.

TYPICAL CHARACTERISTICS (continued)

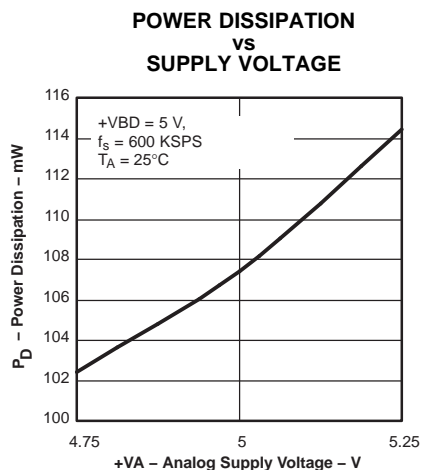


Figure 24.

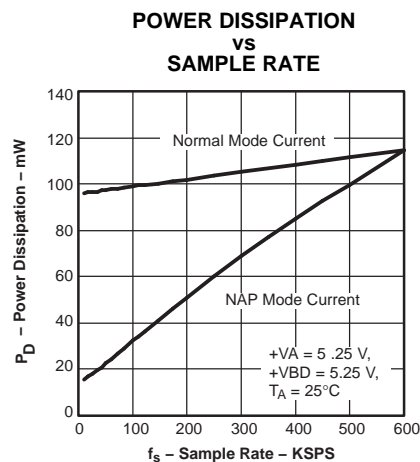


Figure 25.

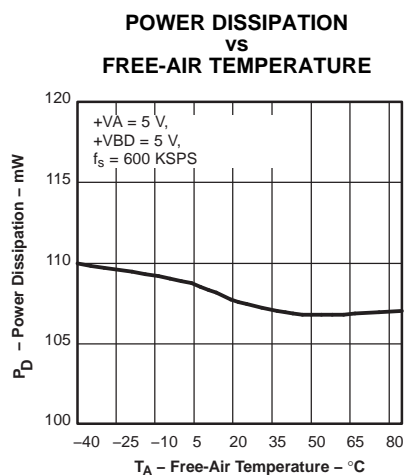


Figure 26.

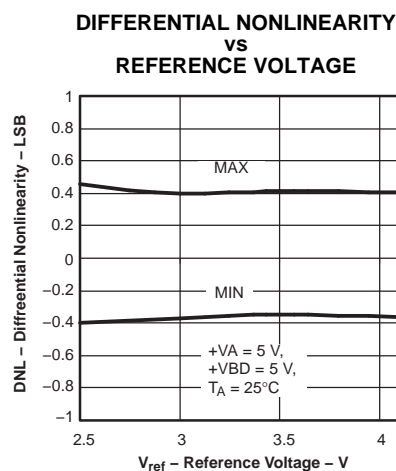


Figure 27.

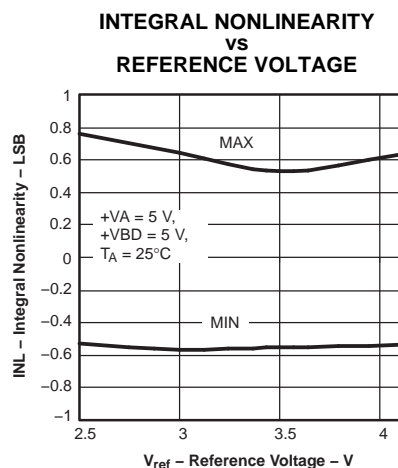


Figure 28.

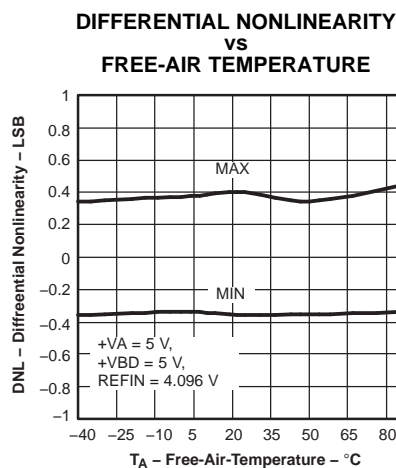


Figure 29.

TYPICAL CHARACTERISTICS (continued)

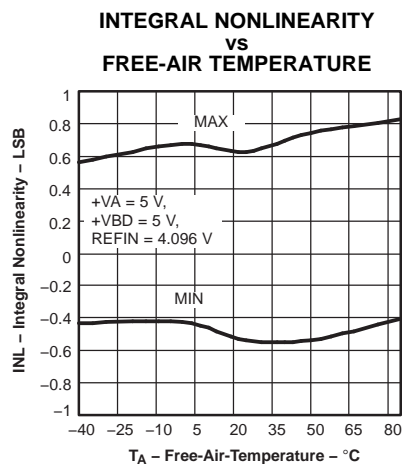


Figure 30.

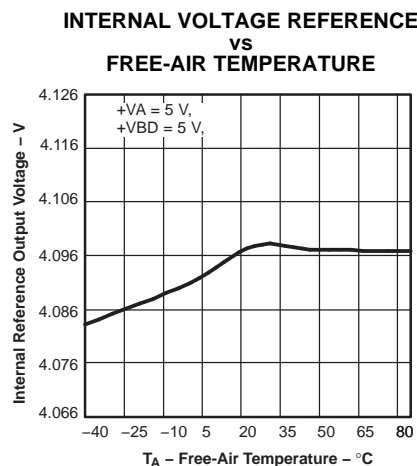


Figure 31.

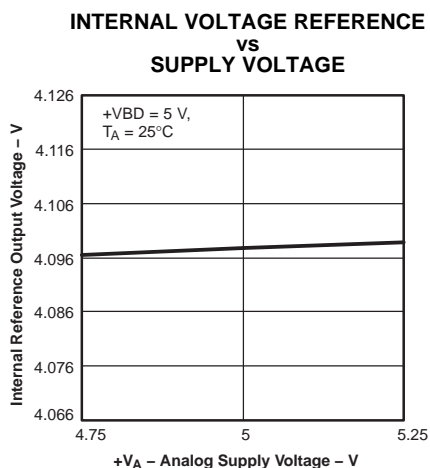


Figure 32.

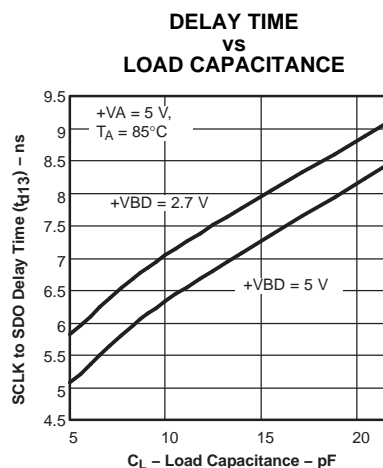


Figure 33.

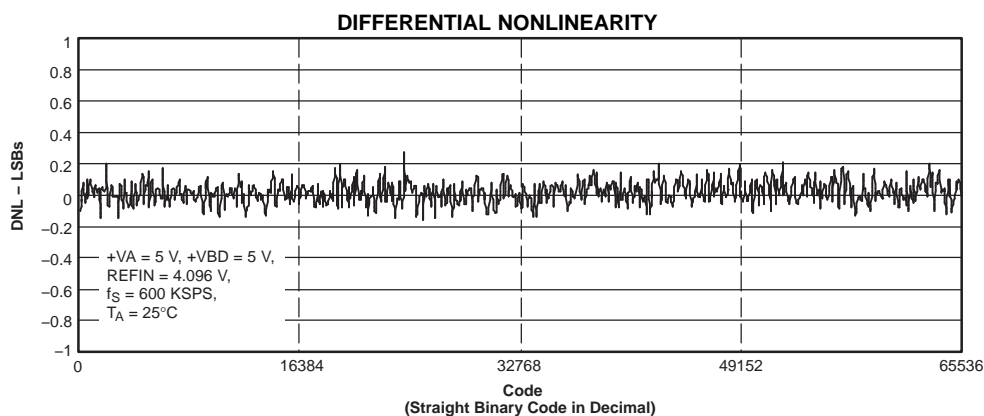


Figure 34.

TYPICAL CHARACTERISTICS (continued)

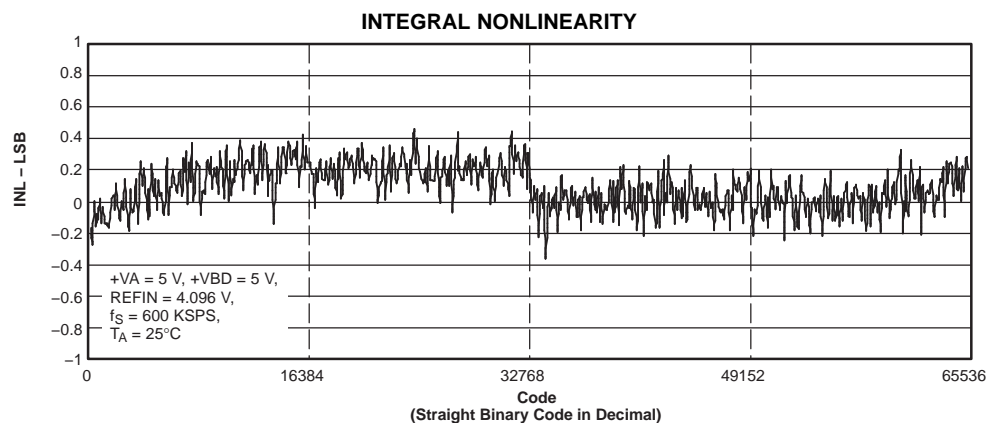


Figure 35.

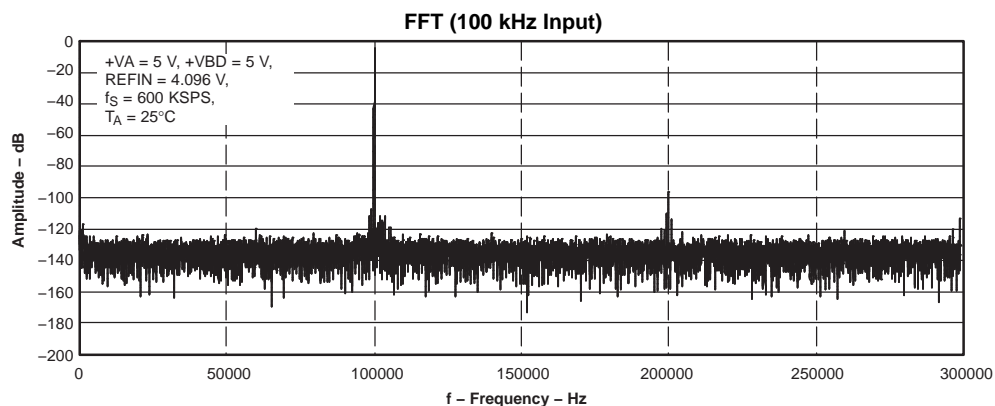


Figure 36.

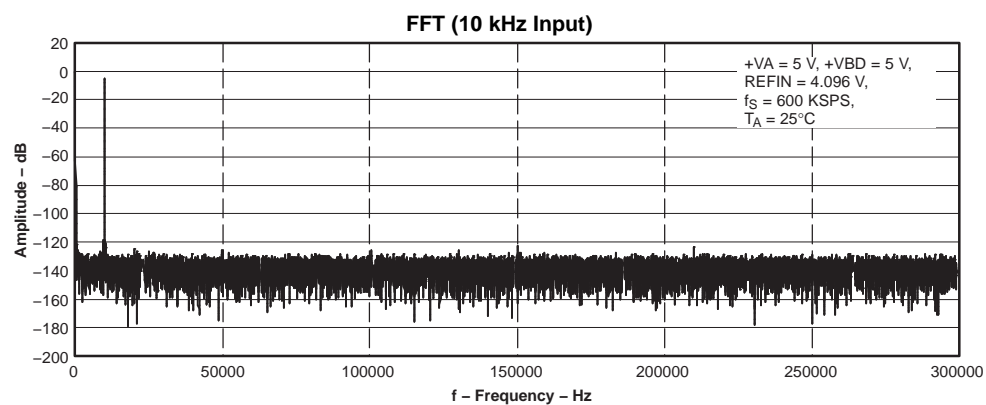
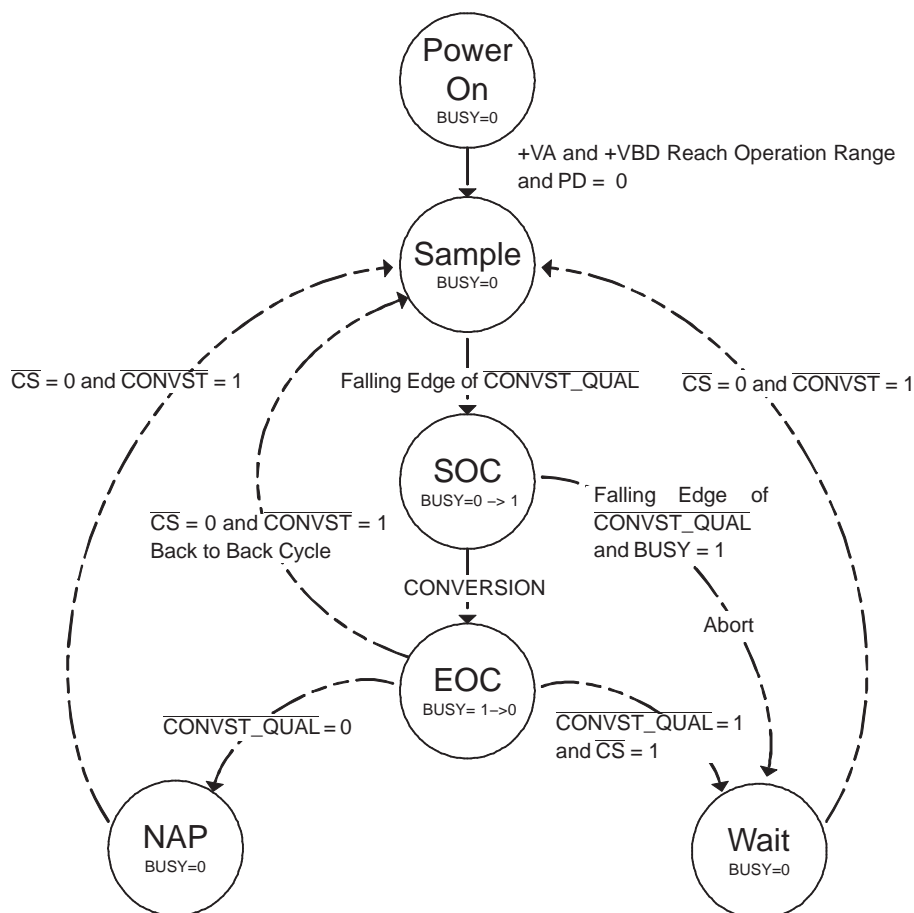


Figure 37.



- A. EOC = End of conversion, SOC = Start of conversion, $\overline{\text{CONVST_QUAL}}$ is $\overline{\text{CONVST}}$ latched by $\overline{\text{CS}} = 0$, see Figure 39.

Figure 38. Device States and Ideal Transitions

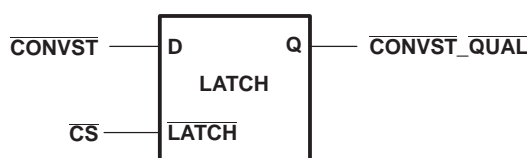


Figure 39. Relationship Between $\overline{\text{CONVST_QUAL}}$, $\overline{\text{CS}}$, and $\overline{\text{CONVST}}$

TIMING DIAGRAMS

In the following descriptions, the signal $\overline{\text{CONVST_QUAL}}$ represents $\overline{\text{CONVST}}$ latched by a low value on $\overline{\text{CS}}$ (see Figure 39).

To avoid performance degradation, there are three quiet zones to be observed (t_{quiet1} and t_{quiet2} are zones before and after the falling edge of $\overline{\text{CONVST_QUAL}}$ while t_{quiet3} is a time zone before the falling edge of BUSY) where there should be no I/O activities. Interface control signals, including the serial clock should remain steady. Typical degradation in performance if these quiet zones are not observed is depicted in the specifications section.

To avoid data loss a read operation should not start around the BUSY falling edge. This is constrained by t_{su2} , t_{su3} , t_{h2} , and t_{h8} .

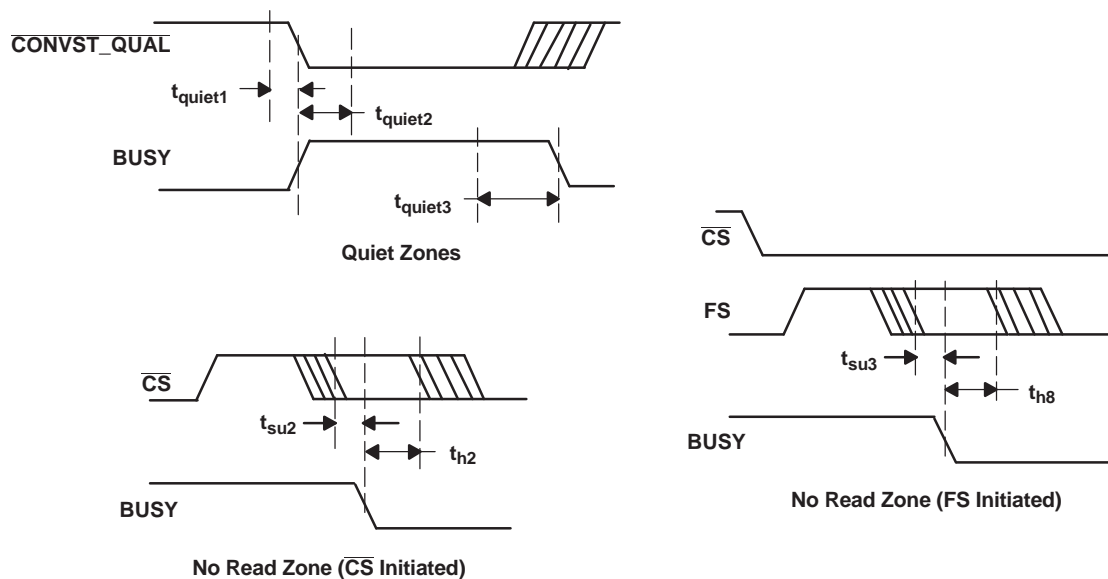


Figure 40. Quiet Zones and No-Read Zones

CONVERSION AND SAMPLING

1. Convert start command:

The device enters the conversion phase from the sampling phase when a falling edge is detected on `CONVST_QUAL`. This is shown in [Figure 41](#), [Figure 42](#), and [Figure 43](#).

2. Sample (acquisition) start command:

The device starts sampling from the wait state or at the end of a conversion if $\overline{\text{CONVST_QUAL}}$ is detected as high and $\overline{\text{CS}}$ as low. This is shown in [Figure 41](#), [Figure 42](#), and [Figure 43](#).

Maintaining this condition when the device has just finished a conversion (as shown in [Figure 41](#)) takes the device immediately into the sampling phase after the conversion phase (back-to-back conversion) and hence achieves maximum throughput. Otherwise, the device enters the wait state.

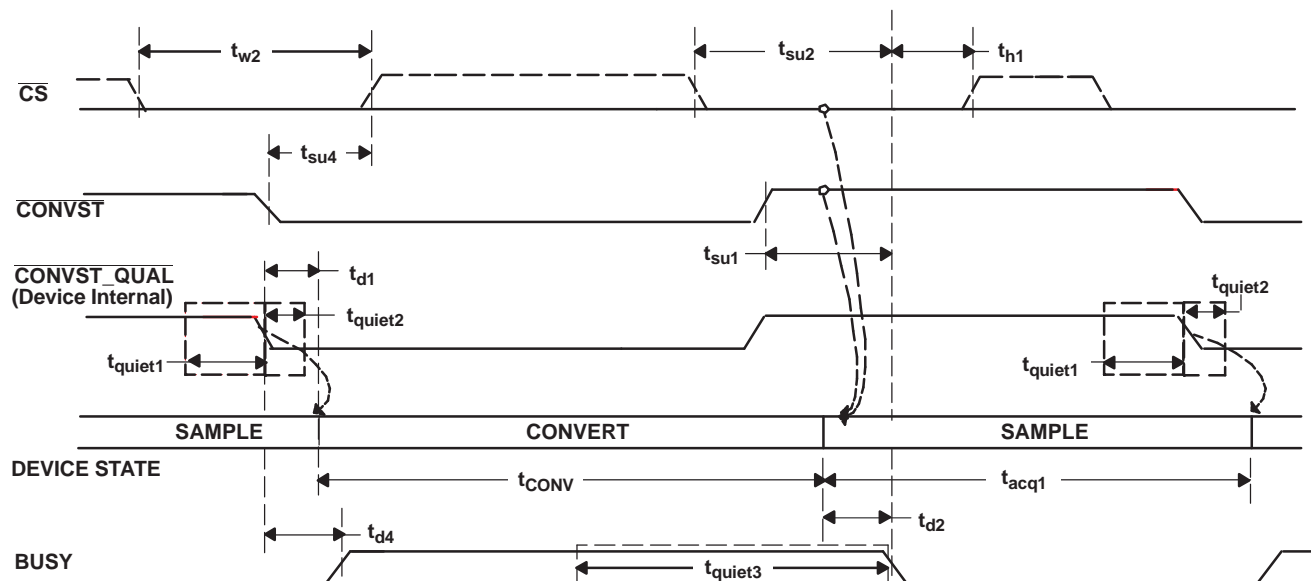


Figure 41. Back-To-Back Conversion and Sample

3. Wait/Nap entry stimulus:

The device enters the wait phase at the end of the conversion if the sample start command is not given. This is shown in Figure 42.

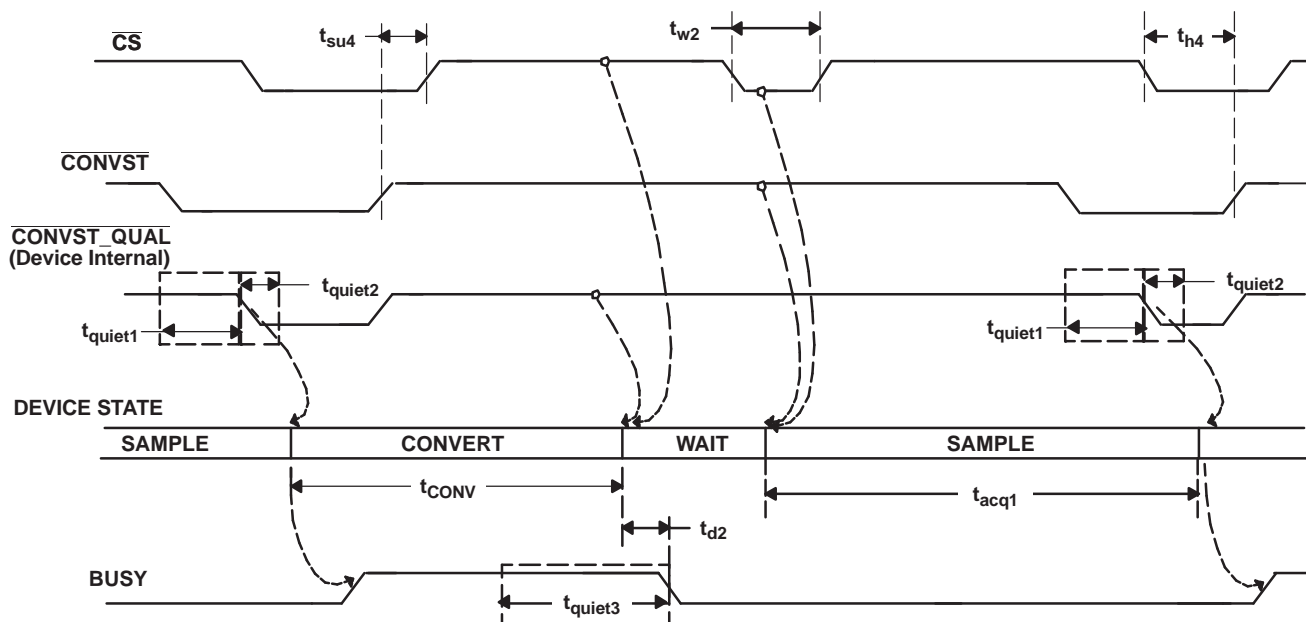


Figure 42. Convert and Sample with Wait

If lower power dissipation is desired and throughput can be compromised, a nap state can be inserted in between cycles (as shown in Figure 43). The device enters a low power (3 mA) state called nap if the end of the conversion happens when CONVST_QUAL is low. The cost for using this special wait state is a longer sampling time (t_{acq2}) plus the nap time.

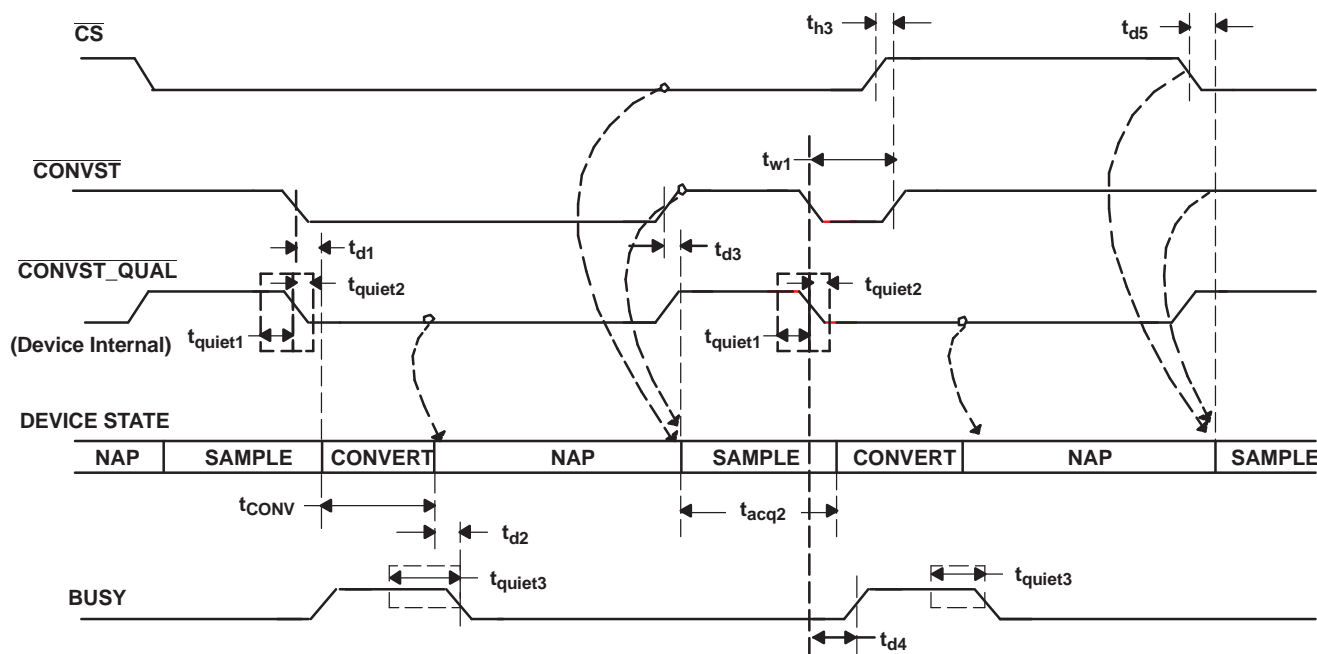


Figure 43. Convert and Sample with Nap

4. Conversion abort command

An ongoing conversion can be aborted by using the conversion abort command. This is done by forcing another start of conversion (a valid `CONVST_QUAL` falling edge) onto an ongoing conversion as shown in Figure 44. The device enters the wait state after an aborted conversion. If the previous conversion was successfully aborted, the device output reads 0xFF00 on SDO.

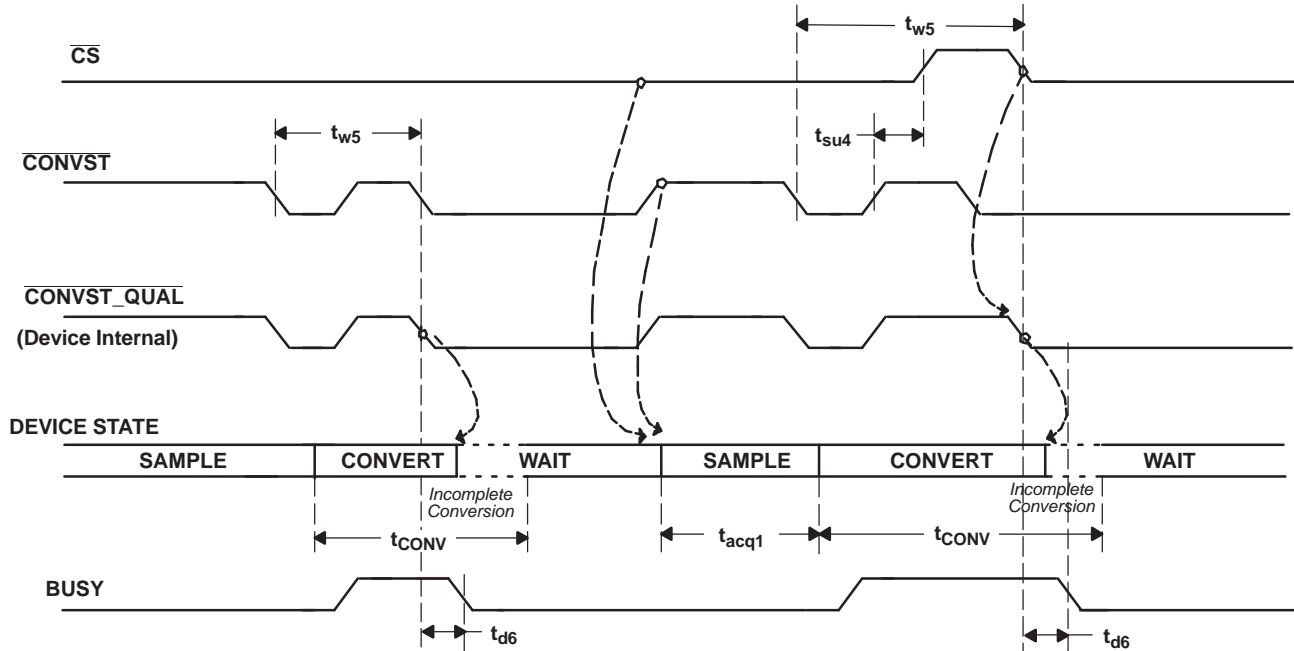


Figure 44. Conversion Abort

DATA READ OPERATION

Data read control is independent of conversion control. Data can be read either during conversion or during sampling. Data that is read during a conversion involves latency of one sample. The start of a new data frame around the fall of `BUSY` is constrained by t_{su2} , t_{su3} , t_{h2} , and t_{h8} .

1. SPI Interface:

A data read operation in SPI interface mode is shown in Figure 45. `FS` must be tied high for operating in this mode. The MSB of the output data is available at the falling edge of \overline{CS} . MSB – 1 is shifted out at the first rising edge after the first falling edge of `SCLK` after \overline{CS} falling edge. Subsequent bits are shifted at the subsequent rising edges of `SCLK`. If another data frame is attempted (by pulling \overline{CS} high and subsequently low) during an active data frame, then the ongoing frame is aborted and a new frame is started.

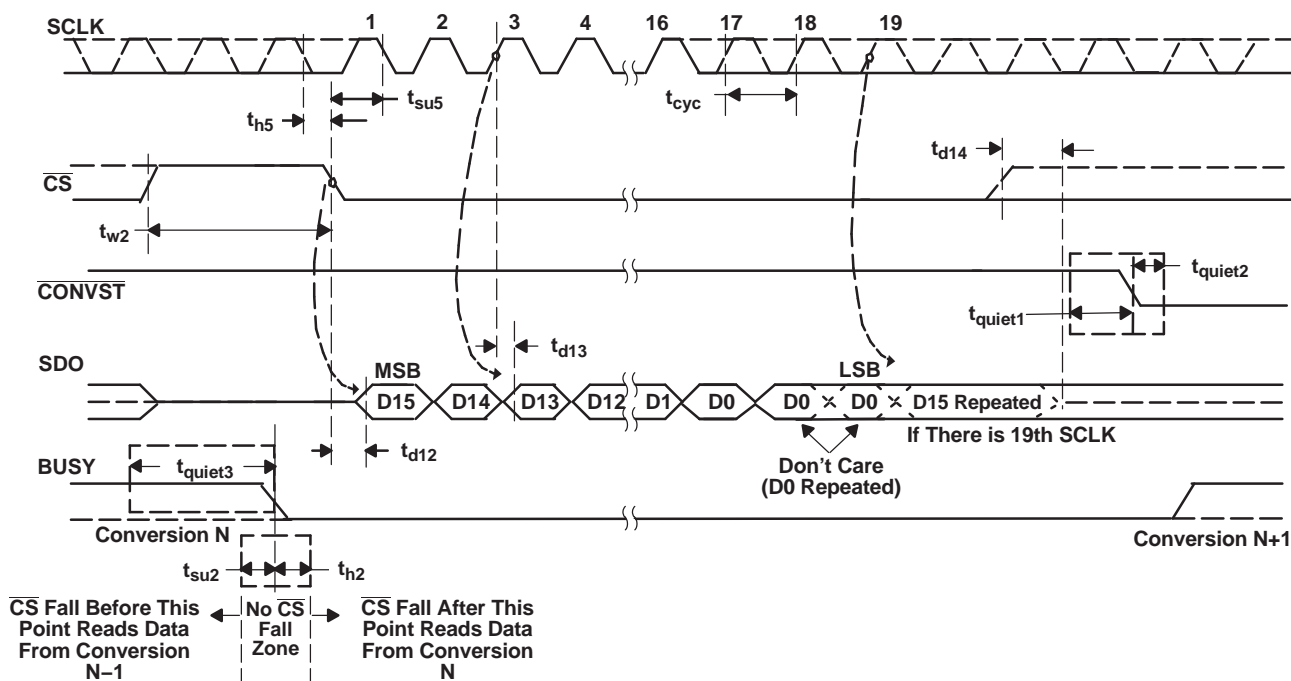


Figure 45. Read Frame Controlled via \overline{CS} (FS = 1)

If another data frame is attempted (by pulling \overline{CS} high and then low) during an active data frame, then the ongoing frame is aborted and a new frame is started.

2. Serial interface using FS:

A data read operation in this mode is shown in Figure 46 and Figure 47. The MSB of the output data is available at the rising edge of FS. MSB – 1 is shifted out at the first rising edge after the first falling edge of SCLK after the FS falling edge. Subsequent bits are shifted at the subsequent rising edges of SCLK.

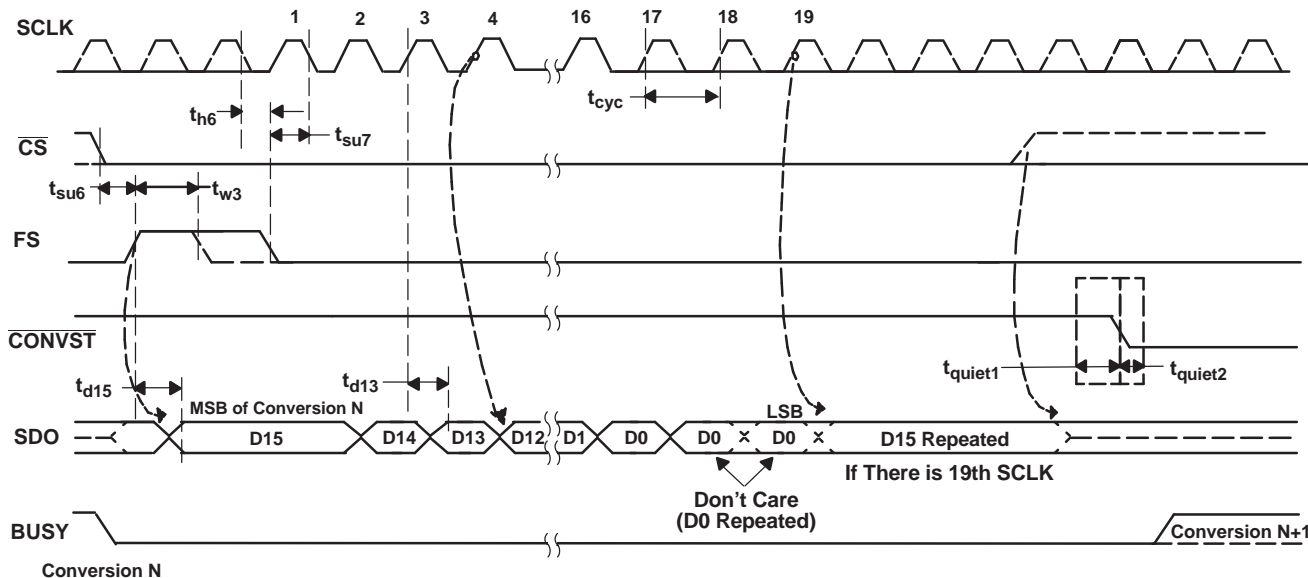


Figure 46. Read Frame Controlled via FS (FS is Low When BUSY Falls)

If FS is high when BUSY falls, the SDO is updated again with the new MSB when BUSY falls. This is shown in Figure 47.

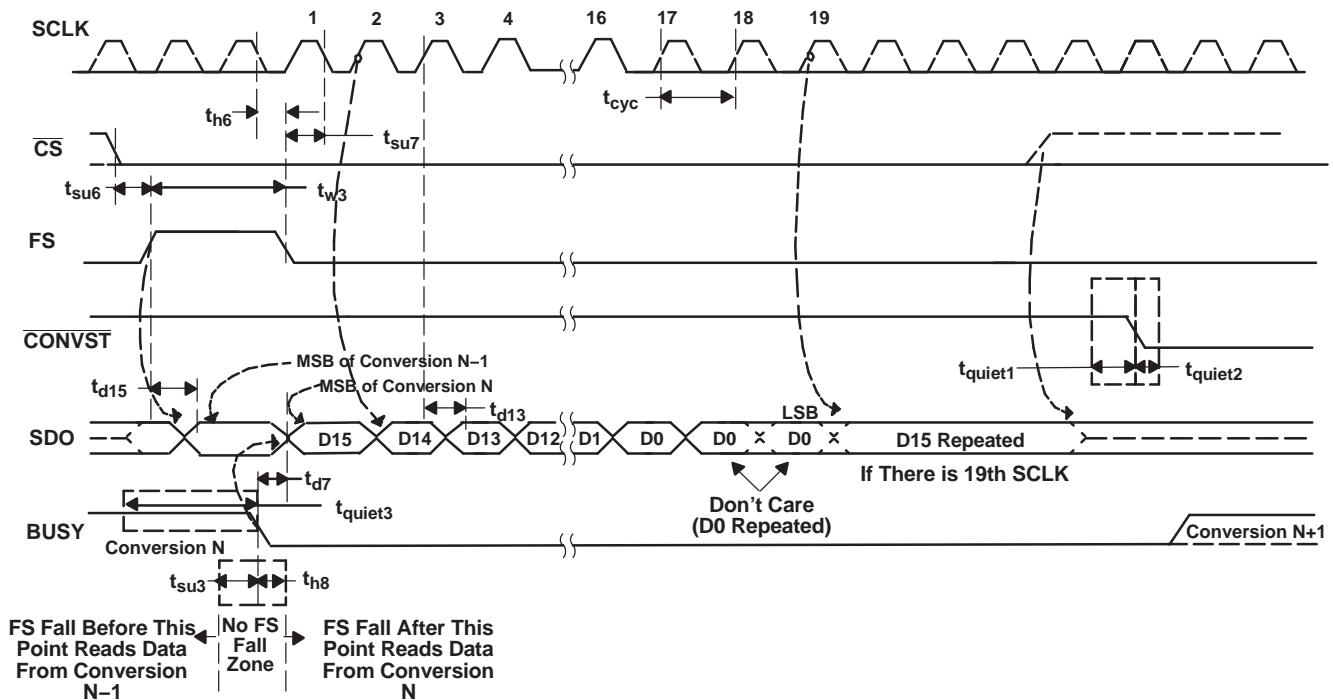


Figure 47. Read Frame Controlled via FS (FS is High When BUSY Falls)

If another data frame is attempted by pulling up FS during an active data frame, then the ongoing frame is aborted and a new frame is started.

PRINCIPLES OF OPERATION

The ADS8370 is a high-speed successive approximation register (SAR) analog-to-digital converter (ADC). The architecture is based on charge redistribution, which inherently includes a sample/hold function.

The device includes a built-in conversion clock, internal reference, and 40-MHz SPI compatible serial interface. The maximum conversion time is 1.16 μ s which is capable of sustaining a 600-kHz throughput.

The analog input is provided to the two input pins: +IN and –IN. When a conversion is initiated, the differential input on these pins is sampled on the internal capacitor array. While a conversion is in progress, both inputs are disconnected from any internal function.

REFERENCE

The ADS8370 has a built-in 4.096-V (nominal value) reference but can operate with an external reference also. When the internal reference is used, pin 9 (REFOUT) should be shorted to pin 8 (REFIN) and a 0.1- μ F decoupling capacitor and a 1- μ F storage capacitor must be connected between pin 8 (REFIN) and pin 7 (REFM) (see [Figure 48](#)). The internal reference of the converter is buffered.

PRINCIPLES OF OPERATION (continued)

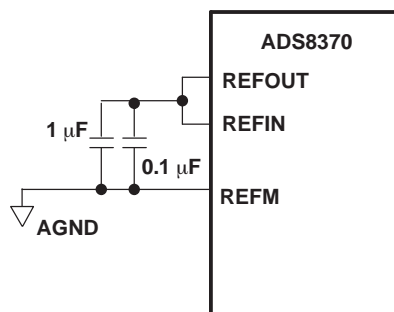


Figure 48. ADS8370 Using Internal Reference

The REFIN pin is also internally buffered. This eliminates the need to put a high bandwidth buffer on the board to drive the ADC reference and saves system area and power. When an external reference is used, the reference must be of low noise, which may be achieved by the addition of bypass capacitors from the REFIN pin to the REFM pin. See Figure 49 for operation of the ADS8370 with an external reference. REFM must be connected to the analog ground plane.

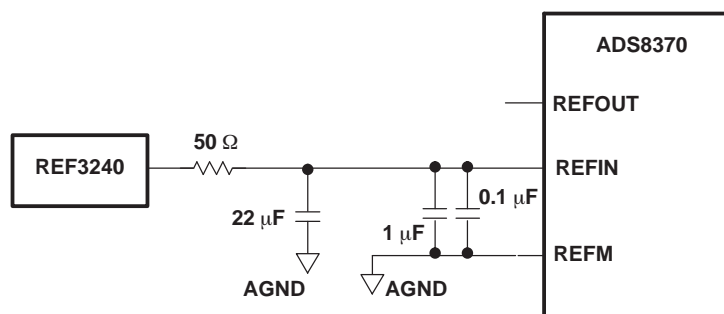


Figure 49. ADS8370 Using External Reference

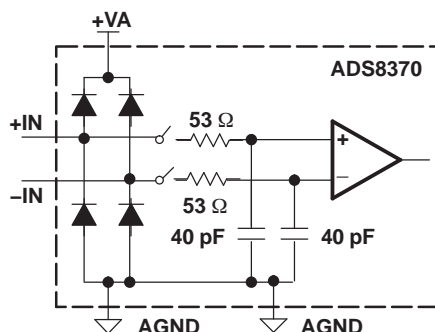


Figure 50. Simplified Analog Input

ANALOG INPUT

When the converter enters hold mode, the voltage difference between the +IN and –IN inputs is captured on the internal capacitor array. The +IN input has a range of –0.2 V to ($+V_{REF} + 0.2$ V), whereas the –IN input has a range of –0.2 V to +0.2 V. The input span [$+IN - (-IN)$] is limited from 0 V to V_{REF} .

The input current on the analog inputs depends upon throughput and the frequency content of the analog input

PRINCIPLES OF OPERATION (continued)

signals. Essentially, the current into the ADS8370 charges the internal capacitor array during the sampling (acquisition) time. After this capacitance has been fully charged, there is no further input current. The source of the analog input voltage must be able to charge the device sampling capacitance (40 pF each from +IN/–IN to AGND) to an 16-bit settling level within the sampling (acquisition) time of the device. When the converter goes into hold mode, the input resistance is greater than 1 G Ω .

Care must be taken regarding the absolute analog input voltage. To maintain the linearity of the converter, the +IN, –IN inputs and the span [+IN – (–IN)] should be within the limits specified. Outside of these ranges, the converter's linearity may not meet specifications.

Care should be taken to ensure that the output impedance of the sources driving +IN and –IN inputs are matched. If this is not observed, the two inputs can have different settling times. This can result in offset error, gain error, and linearity error which vary with temperature and input voltage.

A typical input circuit using TI's THS4031 is shown in Figure 52. In the figure, input from a bipolar source is converted to a unipolar signal for the ADS8370. In the case where the source signal is in range for the ADS8370, the circuit in Figure 51 may be used. Most of the specified performance figure were measured using the circuit in Figure 51.

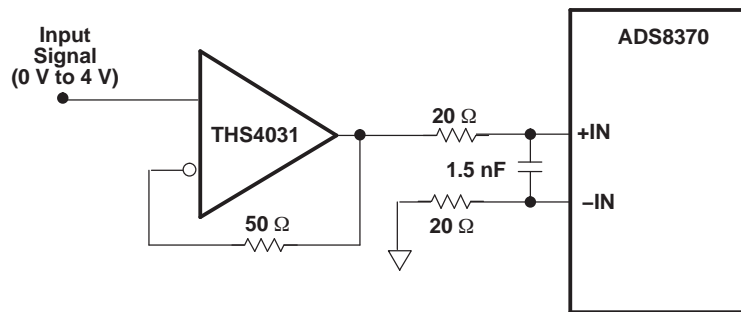


Figure 51. Unipolar Input Drive Configuration

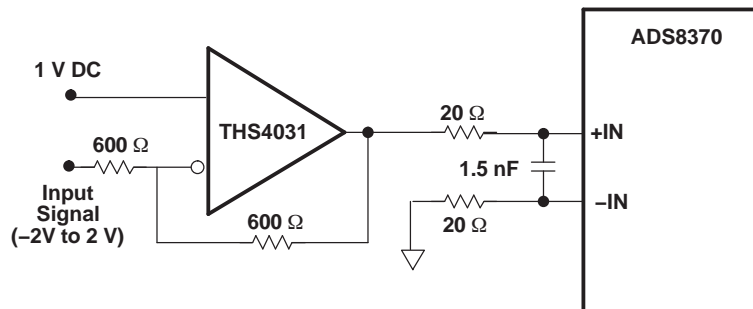


Figure 52. Bipolar Input Drive Configuration

DIGITAL INTERFACE

TIMING AND CONTROL

Conversion and sampling are controlled by the $\overline{\text{CONVST}}$ and $\overline{\text{CS}}$ pins. See the timing diagrams for detailed information on timing signals and their requirements. The ADS8370 uses an internally generated clock to control the conversion rate and in turn the throughput of the converter. SCLK is used for reading converted data only. A clean and low jitter conversion start command is important for the performance of the converter. There is a minimal quiet zone requirement around the conversion start command as mentioned in the timing requirements table.

DIGITAL INTERFACE (continued)

READING DATA

The ADS8370 offers a high speed serial interface that is compatible with the SPI protocol. The device outputs data in either 2's complement format or straight binary format depending on the state of the $\overline{SB}/2C$ pin. Refer to [Table 1](#) for the ideal output codes.

Table 1. Input Voltages and Ideal Output Codes

DESCRIPTION	ANALOG VALUE +IN – (–IN)	DIGITAL OUTPUT (HEXADECIMAL)	
Full-scale range	$(+V_{REF})$	$\overline{SB}/2C$ Pin = 0	$\overline{SB}/2C$ Pin = 1
Least significant bit (LSB)	$(+V_{REF})/2^{16}$		
Full scale	$V_{REF} - 1 \text{ LSB}$	FFFF	7FFF
Mid scale	$(+V_{REF})/2$	8000	0000
Mid scale – 1 LSB	$(+V_{REF})/2 - 1 \text{ LSB}$	7FFF	FFFF
0	0	0000	8000

To avoid performance degradation due to the toggling of device buffers, read operation must not be performed in the specified quiet zones (t_{quiet1} , t_{quiet2} , and t_{quiet3}). Internal to the device, the previously converted data is updated with the new data near the fall of BUSY. Hence, the fall of \overline{CS} and the fall of FS around the fall of BUSY is constrained. This is specified by t_{su2} , t_{su3} , t_{h2} , and t_{h8} in the timing requirements table.

POWER SAVING

The converter provides two power saving modes, full power down and nap. Refer to [Table 2](#) for information on activation/deactivation and resumption time for both modes.

Table 2. Power Save

TYPE OF POWER DOWN	SDO	POWER CONSUMPTION	ACTIVATED BY	ACTIVATION TIME (t_{d16})	RESUME POWER BY
Normal operation	Not 3 stated	22 mA	NA	NA	NA
Full power down (Int Ref, 1- μ F capacitor on REFOUT pin)	3 Stated (t_{d10} timing)	2 μ A	PD = 1	10 μ s	PD = 0
Full power down (Ext Ref, 1- μ F capacitor on REFOUT pin)	3 Stated (t_{d10} timing)	2 μ A	PD = 1	10 μ s	PD = 0
Nap power down	Not 3 stated	3 mA	At EOC and $\overline{CONVST_QUAL} = 0$	200 ns	Sample Start command

FULL POWER-DOWN MODE

Full power-down mode is activated by turning off the supply or by asserting PD to 1. See [Figure 53](#) and [Figure 54](#). The device can be resumed from full power down by either turning on the power supply or by de-asserting the PD pin. The first two conversions produce inaccurate results because during this period the device loads its trim values to ensure the specified accuracy.

If an internal reference is used (with a 1- μ F capacitor installed between the REFOUT and REFM pins), the total resume time (t_{d18}) is 25 ms. After the first two conversions, t_{d17} (4 ms) is required for the trimmed internal reference voltage to settle to the specified accuracy. Only then the converted results match the specified accuracy.

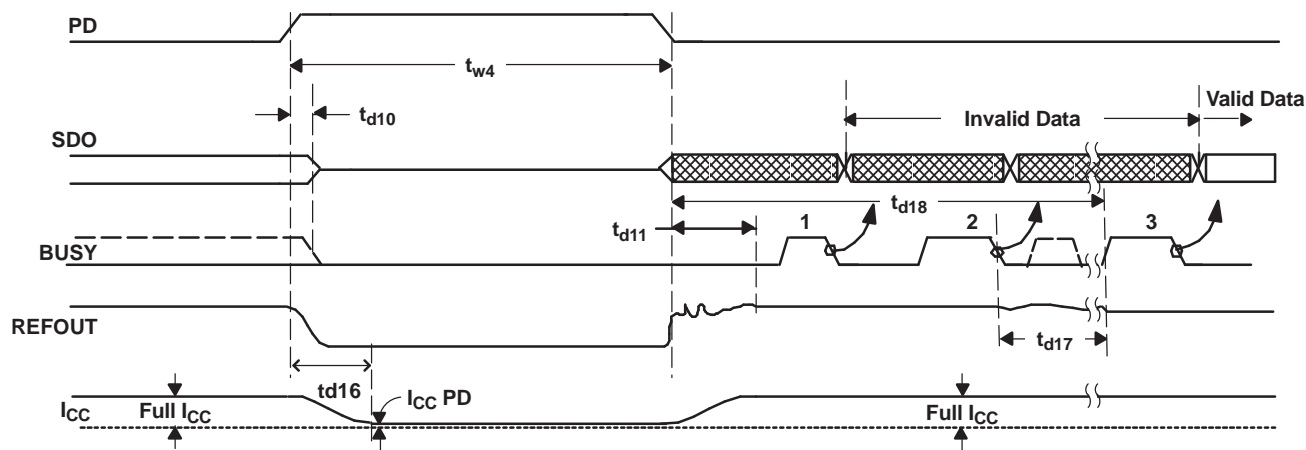


Figure 53. Device Full Power Down/Resume (Internal Reference Used)

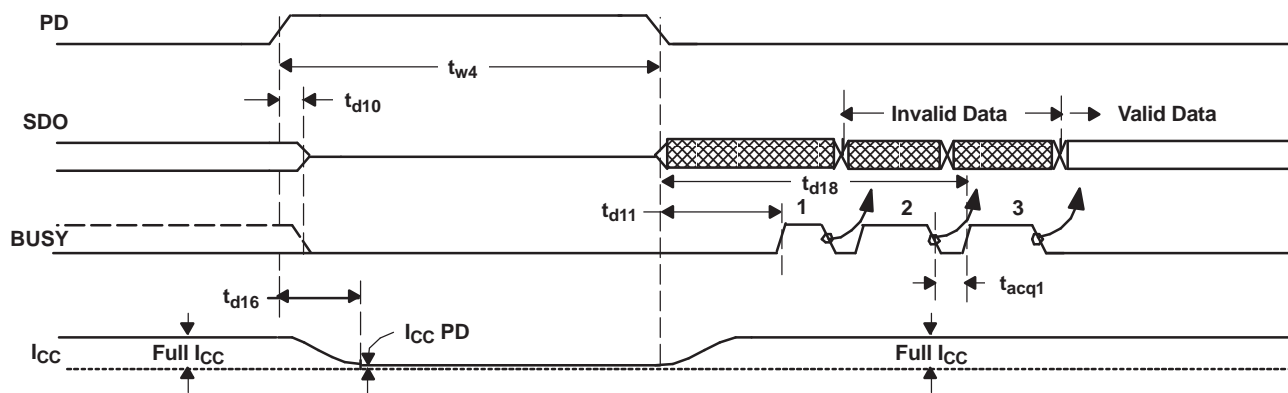


Figure 54. Device Full Power Down/Resume (External Reference Used)

NAP MODE

Nap mode is automatically inserted at the end of a conversion if $\overline{\text{CONVST_QUAL}}$ is held low at EOC. The device can be operated in nap mode at the end of every conversion for saving power at lower throughputs. Another way to use this mode is to convert multiple times and then enter nap mode. The minimum sampling time after a nap state is $t_{\text{acq1}} + t_{\text{d18}} = t_{\text{acq2}}$.

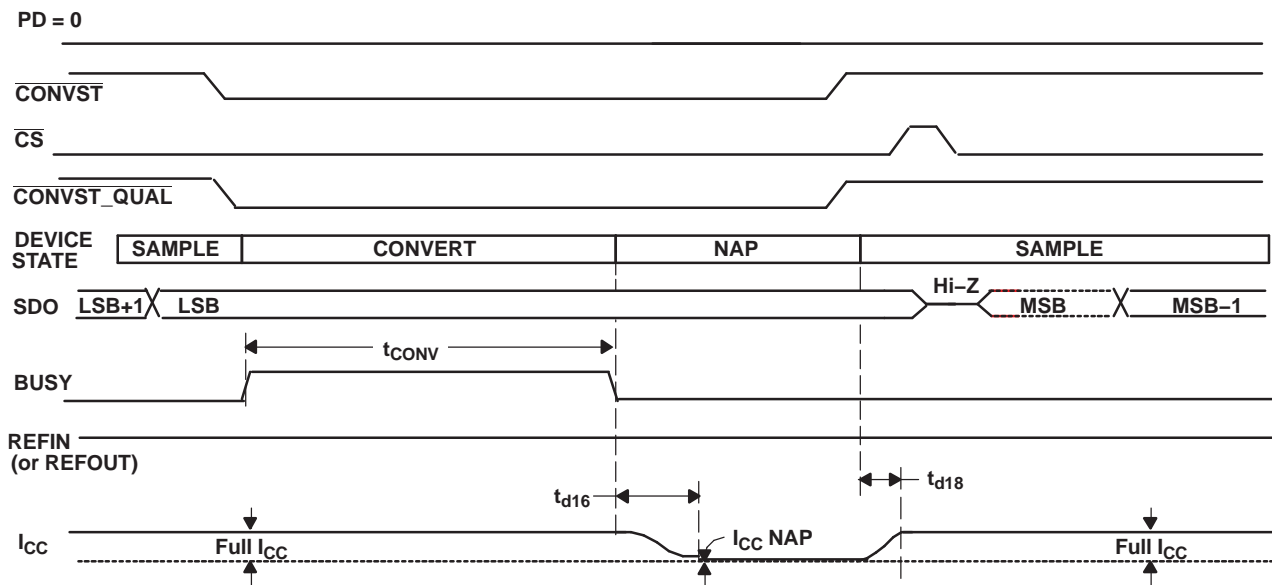


Figure 55. Device Nap Power Down/Resume

LAYOUT

For optimum performance, care should be taken with the physical layout of the ADS8370 circuitry.

Since the ADS8370 offers single-supply operation, it is often used in close proximity with digital logic, microcontrollers, microprocessors, and digital signal processors. The more the digital logic in the design and the higher the switching speed, the greater the need for better layout and isolation of the critical analog signals from these switching digital signals.

The basic SAR architecture is sensitive to glitches or sudden changes on the power supply, reference, ground connections and digital inputs that occur just prior to the end of sampling and just prior to the latching of the analog comparator. Such glitches might originate from switching power supplies, nearby digital logic, or high power devices. Noise during the end of sampling and the latter half of the conversion must be kept to a minimum (the former half of the conversion is not very sensitive since the device uses a proprietary error correction algorithm to correct for the transient errors made here).

The degree of error in the digital output depends on the reference voltage, layout, and the exact timing and degree of the external event.

On average, the ADS8370 draws very little current from an external reference as the reference voltage is internally buffered. If the reference voltage is external, it must be ensured that the reference source can drive the bypass capacitor without oscillation. A 0.1- μ F bypass capacitor is recommended from pin 8 directly to pin 7 (REFM).

The AGND and BDGND pins should be connected to a clean ground point. In all cases, this should be the *analog* ground. Avoid connections that are too close to the grounding point of a microcontroller or digital signal processor. If required, run a ground trace directly from the converter to the power supply entry point. The ideal layout consists of an analog ground plane dedicated to the converter and associated analog circuitry.

As with the AGND connections, +VA should be connected to a +5-V power-supply plane or trace that is separate from the connection for digital logic until they are connected at the power entry point. Power to the ADS8370 should be clean and well bypassed. A 0.1- μ F ceramic bypass capacitor should be placed as close to the device as possible. See Table 3 for the placement of these capacitors. In addition, a 1- μ F capacitor is recommended. In some situations, additional bypassing may be required, such as a 100- μ F electrolytic capacitor or even a *Pi* filter made up of inductors and capacitors—all designed to essentially low-pass filter the +5-V supply, removing the high frequency noise.

Table 3. Power Supply Decoupling Capacitor Placement

SUPPLY PINS	CONVERTER ANALOG SIDE	CONVERTER DIGITAL SIDE
Pair of pins requiring a shortest path to decoupling capacitors	(2,3); (5,6); (15,16); (17,18)	(20,21)
Pins requiring no decoupling	4, 14, 19	

When using the internal reference, ensure a shortest path from REFOUT (pin 9) to REFIN (pin 8) with the bypass capacitor directly between pins 8 and 7.

APPLICATION INFORMATION

EXAMPLE DIGITAL STIMULUS

The use of the ADS8370 is very straightforward. The following timing diagram shows one example of how to achieve a 600-KSPS throughput using a SPI compatible serial interface.

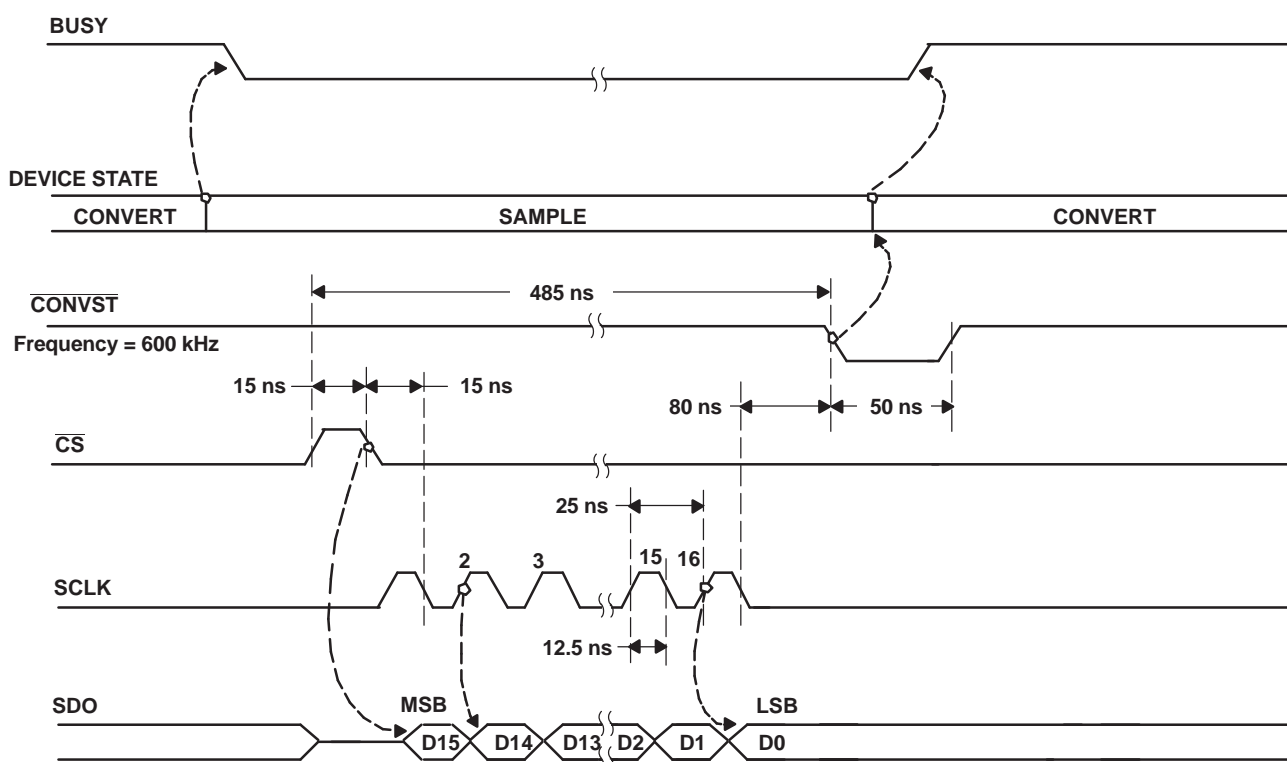


Figure 56. Example Stimulus in SPI Mode (FS =1), Back-To-Back Conversion that Achieves 600 KSPS

APPLICATION INFORMATION (continued)

It is also possible to use the frame sync signal, FS. The following timing diagram shows how to achieve a 600-KSPS throughput using a modified serial interface with FS active.

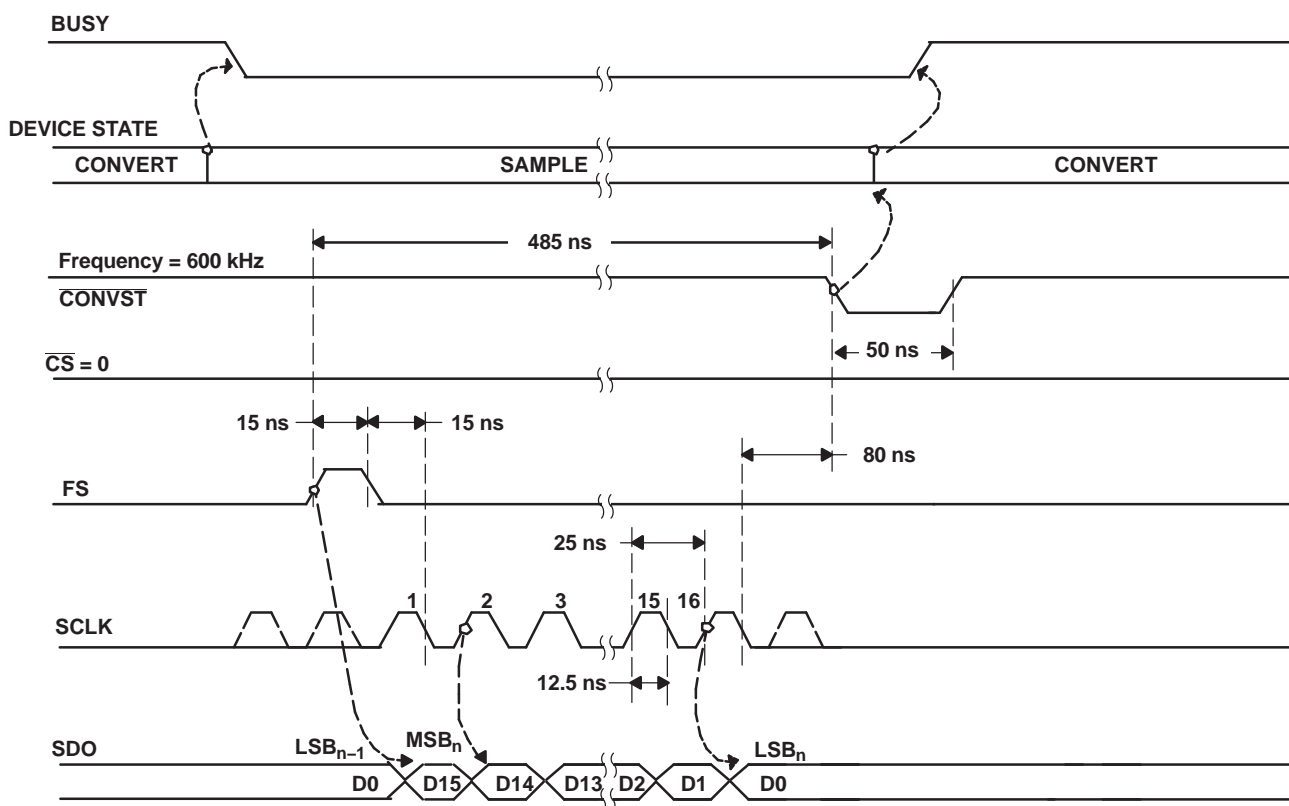


Figure 57. Example Stimulus in Serial Interface With FS Active, Back-To-Back Conversion that Achieves 600 KSPS

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
ADS8370IBRHPT	ACTIVE	VQFN	RHP	28	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	ADS8370I B	Samples
ADS8370IRHPT	ACTIVE	VQFN	RHP	28	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	ADS8370I	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ADS8370IBRHPT	VQFN	RHP	28	250	180.0	16.4	6.3	6.3	1.5	12.0	16.0	Q2
ADS8370IRHPT	VQFN	RHP	28	250	180.0	16.4	6.3	6.3	1.5	12.0	16.0	Q2

TAPE AND REEL BOX DIMENSIONS

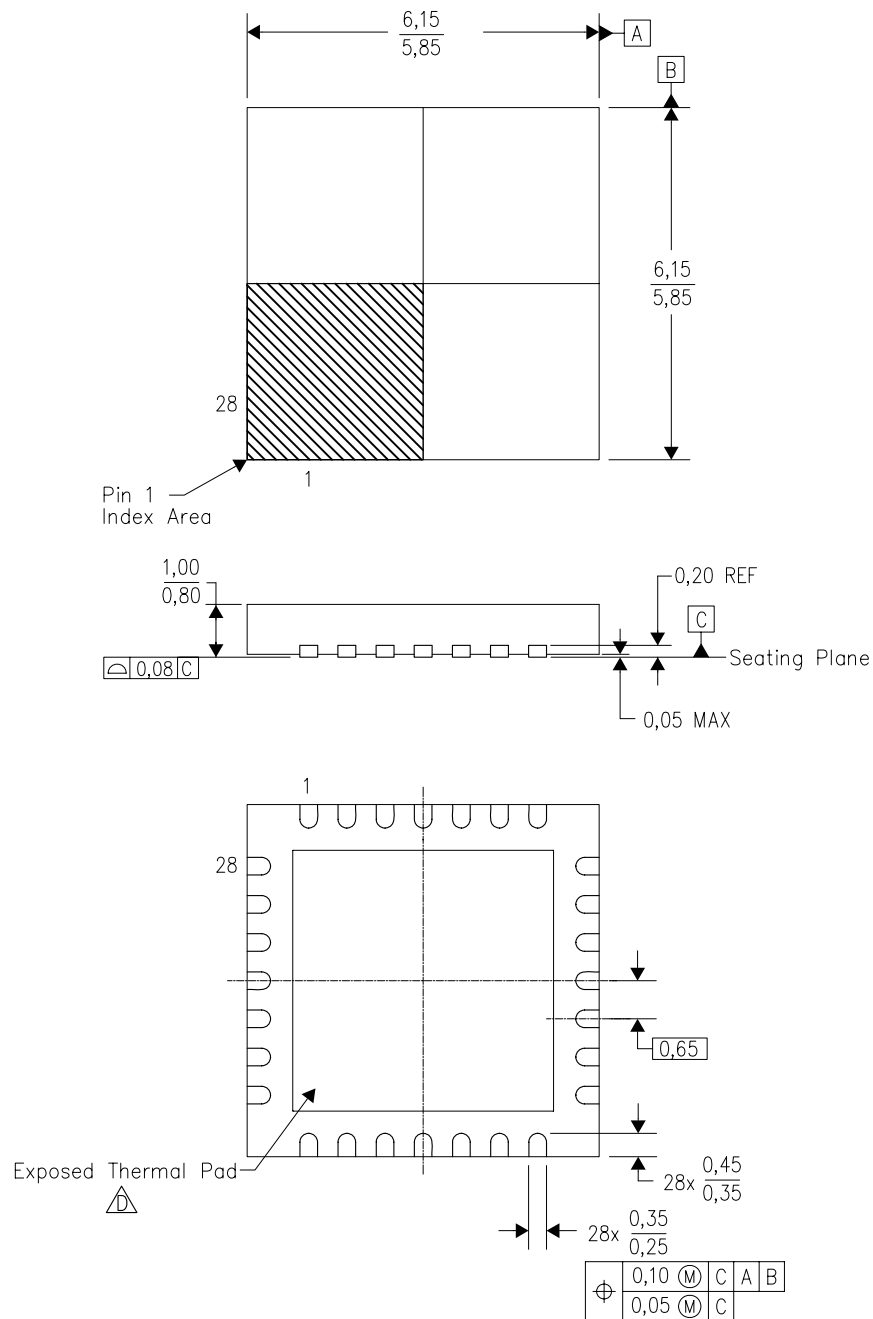


*All dimensions are nominal


Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ADS8370IBRHPT	VQFN	RHP	28	250	213.0	191.0	55.0
ADS8370IRHPT	VQFN	RHP	28	250	213.0	191.0	55.0

RHP (S-PVQFN-N28)

PLASTIC QUAD FLATPACK NO-LEAD



4205387/C 01/11

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. QFN (Quad Flatpack No-Lead) Package configuration.
 -  The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.

THERMAL PAD MECHANICAL DATA

RHP (S-PVQFN-N28)

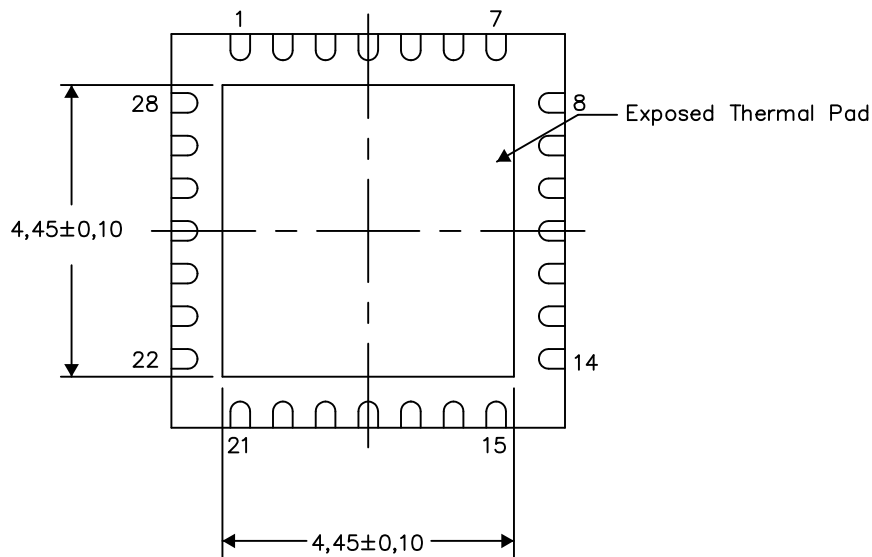
PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

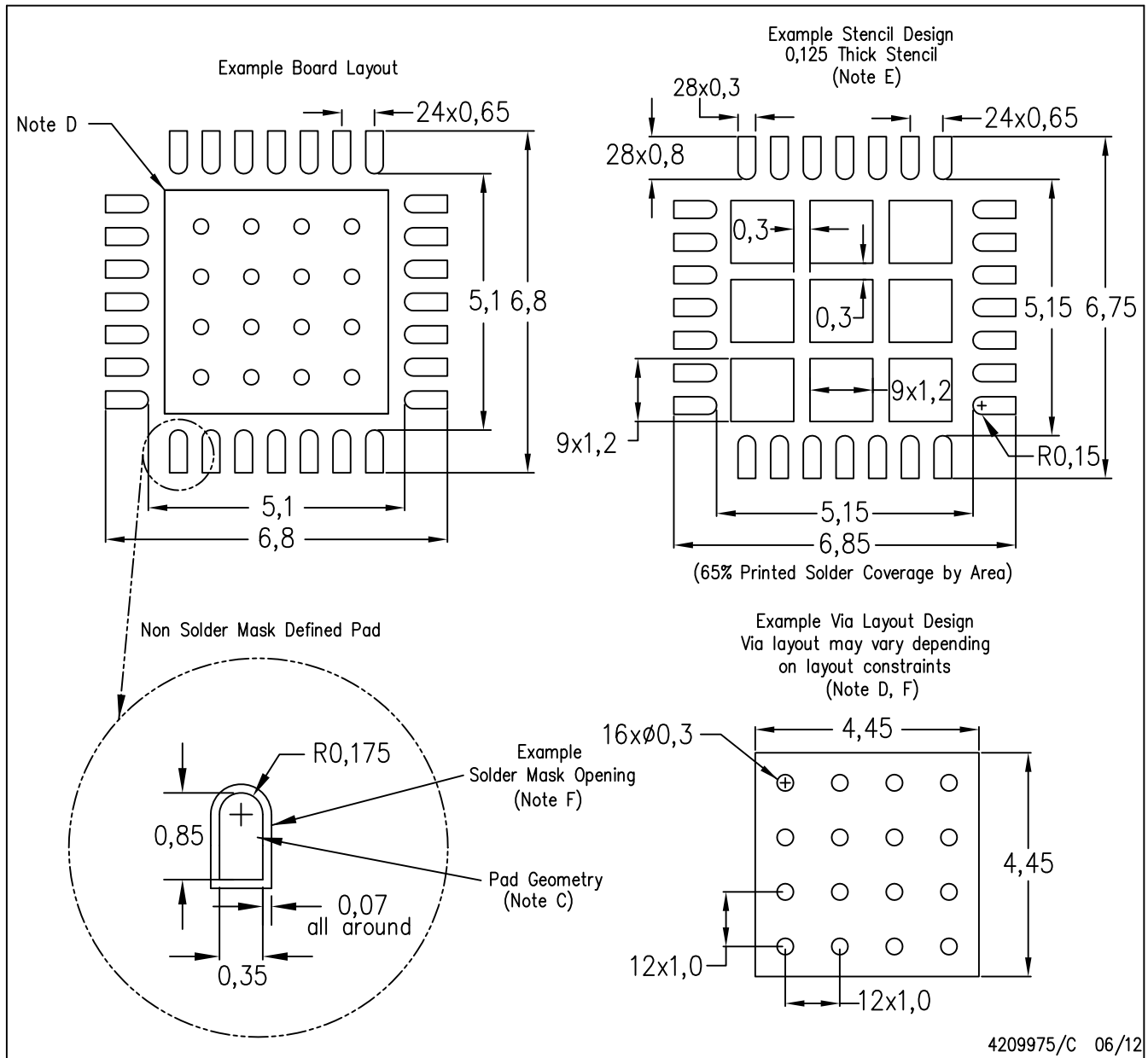
Exposed Thermal Pad Dimensions

4206484/F 06/12

NOTE: All linear dimensions are in millimeters

RHP (S-PVQFN-N28)

PLASTIC QUAD FLATPACK NO-LEAD



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <<http://www.ti.com>>.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
 - Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.

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